7 + 1 Channel DC/DC PMU with Li-Ion Battery Charger for DSC

General Description

The RT5002 is a complete power supply solution for digital still cameras and other handheld devices. It includes a 7+1 channel DC/DC power converter unit, a single-cell Li-ion battery charger, and an I^2C control interface.

The power converter unit includes one synchronous step-up converter and three synchronous step-down converters for DSP core, I/O, Motor, and memory power supply, one synchronous high voltage step-up converter and one asynchronous inverting converter for CCD± bias, one WLED driver in either synchronous high voltage step-up or current source operation, and one low quiescent LDO for RTC application. All converters are internally frequency compensated and integrate power MOSFETs. The power converter unit provides complete protection functions: over current, thermal shutdown, over voltage, over-load, and under voltage protection.

The battery charger includes Auto Power Path Management (APPM). No external MOSFETs are required. The charger enters sleep mode when power is removed. Charging tasks are optimized by using a control algorithm to vary the charge rate, including pre-charge mode, fast charge mode and constant voltage mode. The charge current can also be programmed with an external resistor and modified via the I^2C control interface. The scope that the battery regulation voltage can be modified via the I^2C interface depends on the battery temperature. The internal thermal feedback circuitry regulates the die temperature to optimize the charge rate for all ambient temperatures. The charging task will always be terminated in constant voltage mode when the charging current reduces to the termination current of 10% x I_{CHG_FAST}. The charger includes under voltage and over-voltage protection for the supply input voltage, V_{IN}.

Applications

- DSC

Features

Power Converter Unit :

- **One Channel LV Sync Step-Up and Three Channel LV Sync Step-Down**
  - **Up to 95% Efficiency**
- **One Sync Step-Up and One Async Inverting for CCD± bias**
- **One WLED Driver in either Sync Step-Up or Current Source Operation**
  - **WLED Driver with Dimming Control**
  - **Step-Up Mode with LED Open Protection (OVP7)**
- **One Low Quiescent LDO with Reverse Leakage Prevention for RTC Power Supply**
- **Preset On/Off Sequence of CH1, CH2, CH3, CH4 (1→3→4→2)**
- **Two Preset On/Off Sequence of CH5, CH6 (5→6 or 6→5)**
- **All Power Switches Integrated with Internal Compensation**
- **All Step-Up Converters with Load Disconnect**
- **Wake Up Impulse to Monitor BAT and VIN Plug-In**

Charger Unit :

- **28V Maximum Rating for VIN Power**
- **Selectable Power Current Limit (0.1A / 0.5A / 1.5A)**
- **Auto Power Path Management (APPM) and Integrated Power MOSFETs**
- **Battery Charging Current Control**
- **Battery Regulation Voltage Control**
- **Programmable Charging Current and Safe Charge Timer**
- **Under Voltage and Over Voltage Protection**
- **Optimized Charge Rate via Thermal Feedback**
- **Interrupt Indicator to Fault/Status Events**
- **I^2C Control Interface : Support Fast Mode up to 400kb/s**
- **Voltage Divider for Sensing Battery Voltage Level**
- **Small 40-Lead WQFN Package**
- **RoHS Compliant and Halogen Free**

Ordering Information

RT5002□□

Package Type
QW : WQFN-40L 5x5 (W-Type)

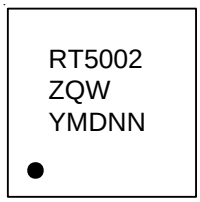
Lead Plating System
Z : ECO (Ecological Element with Halogen Free and Pb free)

Note :

Richtek products are :

- RoHS compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.
- Suitable for use in SnPb or Pb-free soldering processes.

Marking Information

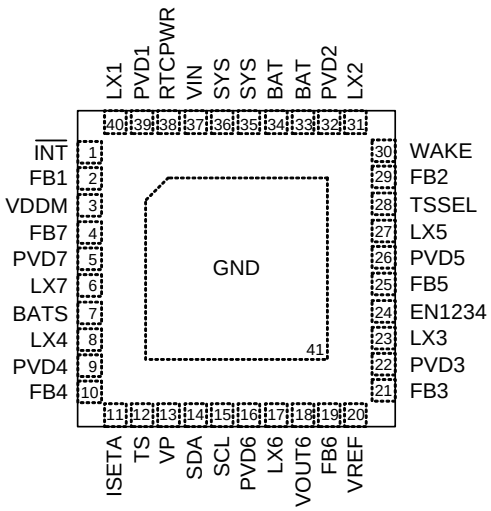


RT5002ZQW : Product Number

YMDNN : Date Code

Pin Configurations

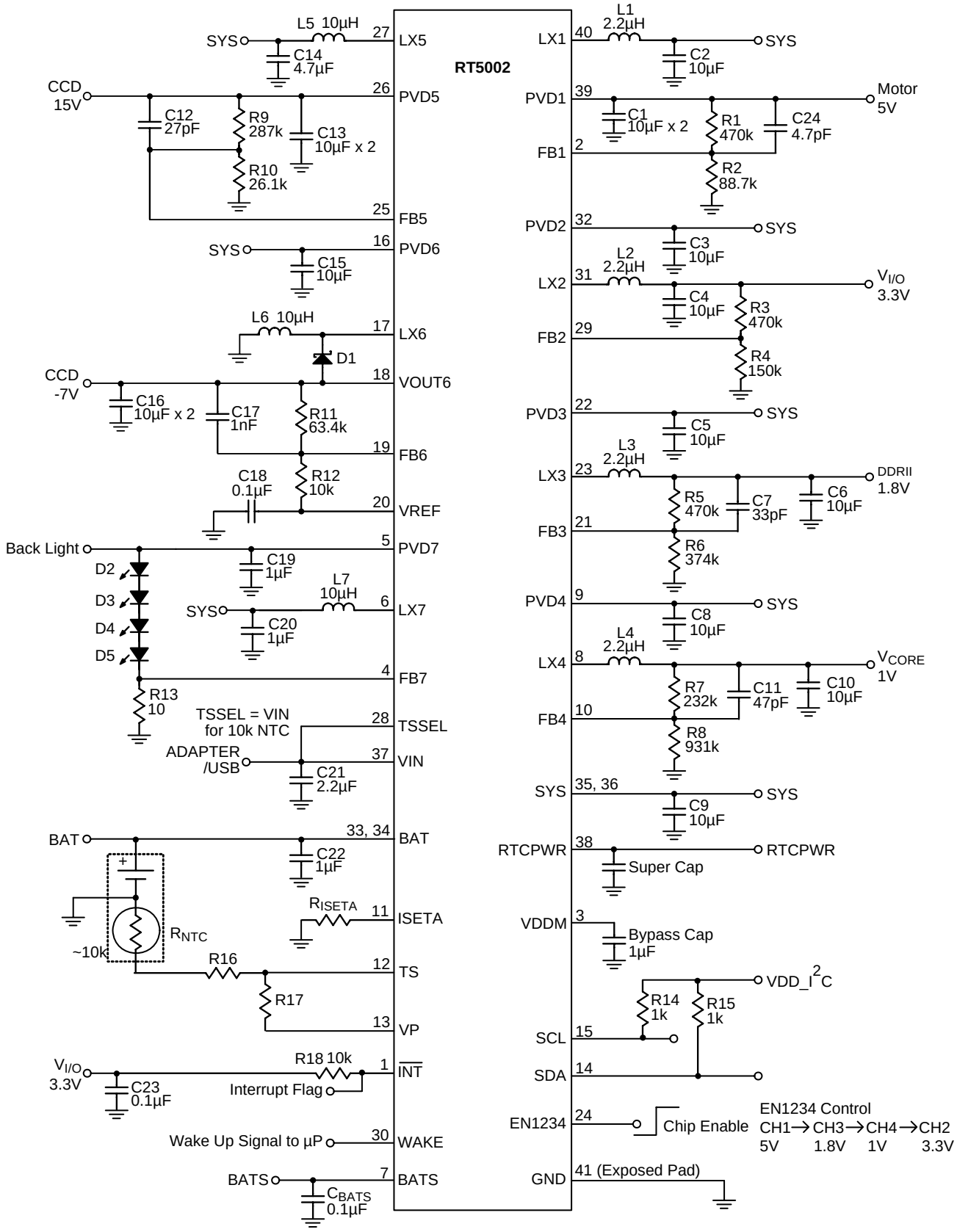
(TOP VIEW)



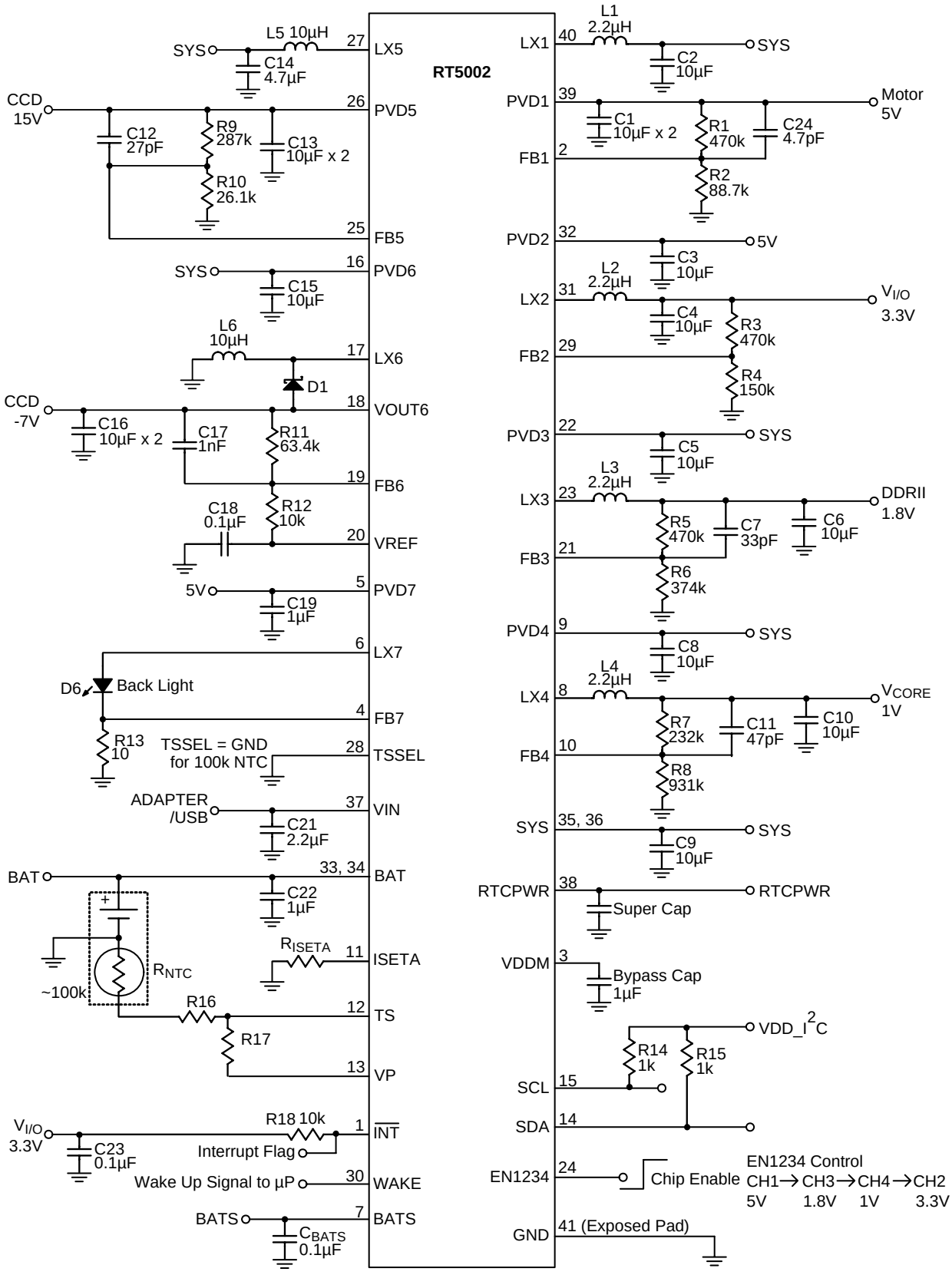
WQFN-40L 5x5

Typical Application Circuit

For 4-LED Application



For 1-LED Application



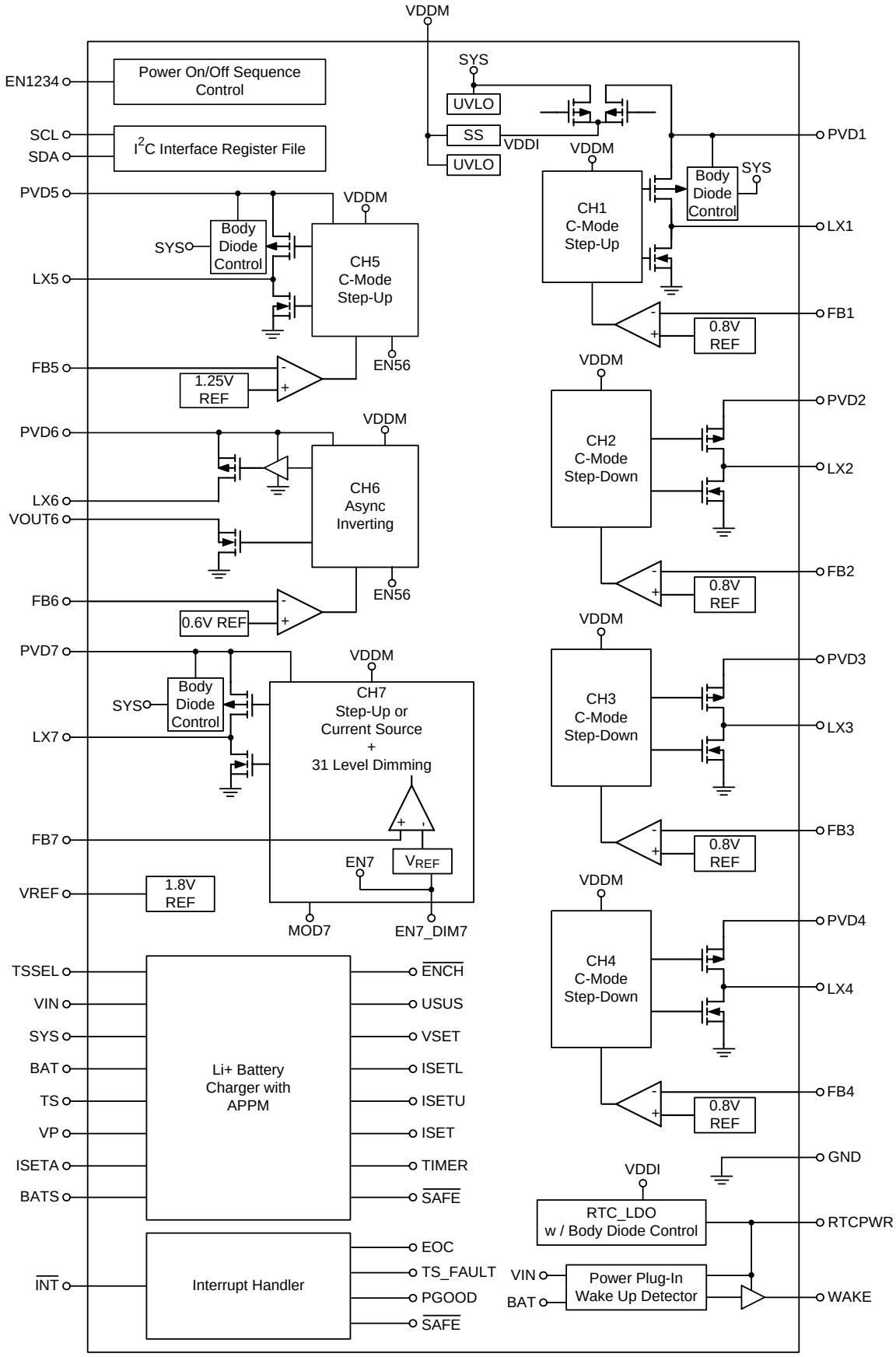
Functional Pin Description

Pin No.	Pin Name	Pin Function
1	$\overline{INT}$	Interrupt Indicator Open Drain Output. If any toggle events of TS_FAULT, PGOOD, EOC, or $\overline{SAFE}$ happen, the output $\overline{INT}$ goes low. After I^2C register bank address 0x2 is read or power on reset, $\overline{INT}$ goes high.
2	FB1	Feedback Input of CH1.
3	VDDM	IC Analog Power Pin.
4	FB7	Feedback Input of CH7 in Step-Up Mode or Current Sink Pin of CH7 in Current Source Mode.
5	PVD7	Power Output of CH7
6	LX7	Switch Node of CH7 in Step-Up Mode.
7	BATS	Output pin of voltage divider for battery voltage level sensing enabled after CH2 soft-start end. BATS voltage is about 60% of BAT.
8	LX4	Switch Node of CH4.
9	PVD4	Power Input of CH4.
10	FB4	Feedback Input of CH4.
11	ISETA	Charge Current Set Input. Connect a resistor (R_{ISETA}) between ISETA and GND.
12	TS	Temperature Sense Input. The TS pin connects to a battery's thermistor to determine whether the battery is too hot or too cold to be charged. If the battery's temperature is out of range, charging is paused until it re-enters the valid range. TS also detects whether the battery (with NTC) is present or not.
13	VP	Power Output of 3.3V Buffer for Battery Temperature Sensing.
14	SDA	Data Signal Pin of I^2C Interface.
15	SCL	Clock Signal Pin of I^2C Interface.
16	PVD6	Power Input of CH6.
17	LX6	Switch Node of CH6.
18	VOUT6	Sense Input of CH6 Inverting Output Node.
19	FB6	Feedback Input of CH6.
20	VREF	1.8V Reference Output.
21	FB3	Feedback Input of CH3.
22	PVD3	Power Input of CH3.
23	LX3	Switch Node of CH3.
24	EN1234	Enable Pin of CH1, CH2, CH3, and CH4.
25	FB5	Feedback Input of CH5.
26	PVD5	Power Output of CH5.
27	LX5	Switch Node of CH5.
28	TSSEL	Input Pin to Select Temperature Sensing Thresholds. Thresholds of TSSEL = H are 60% and 38% of VP voltage. Thresholds of TSSEL = L are 74% and 28% of VP voltage.
29	FB2	Feedback Input of CH2.
30	WAKE	Wake-Up Impulse Push-Pull Output. If VIN or BAT plug in, WAKE pin generates one 55ms width high pulse to notify micro processor.
31	LX2	Switch Node of CH2.
32	PVD2	Power Input of CH2.

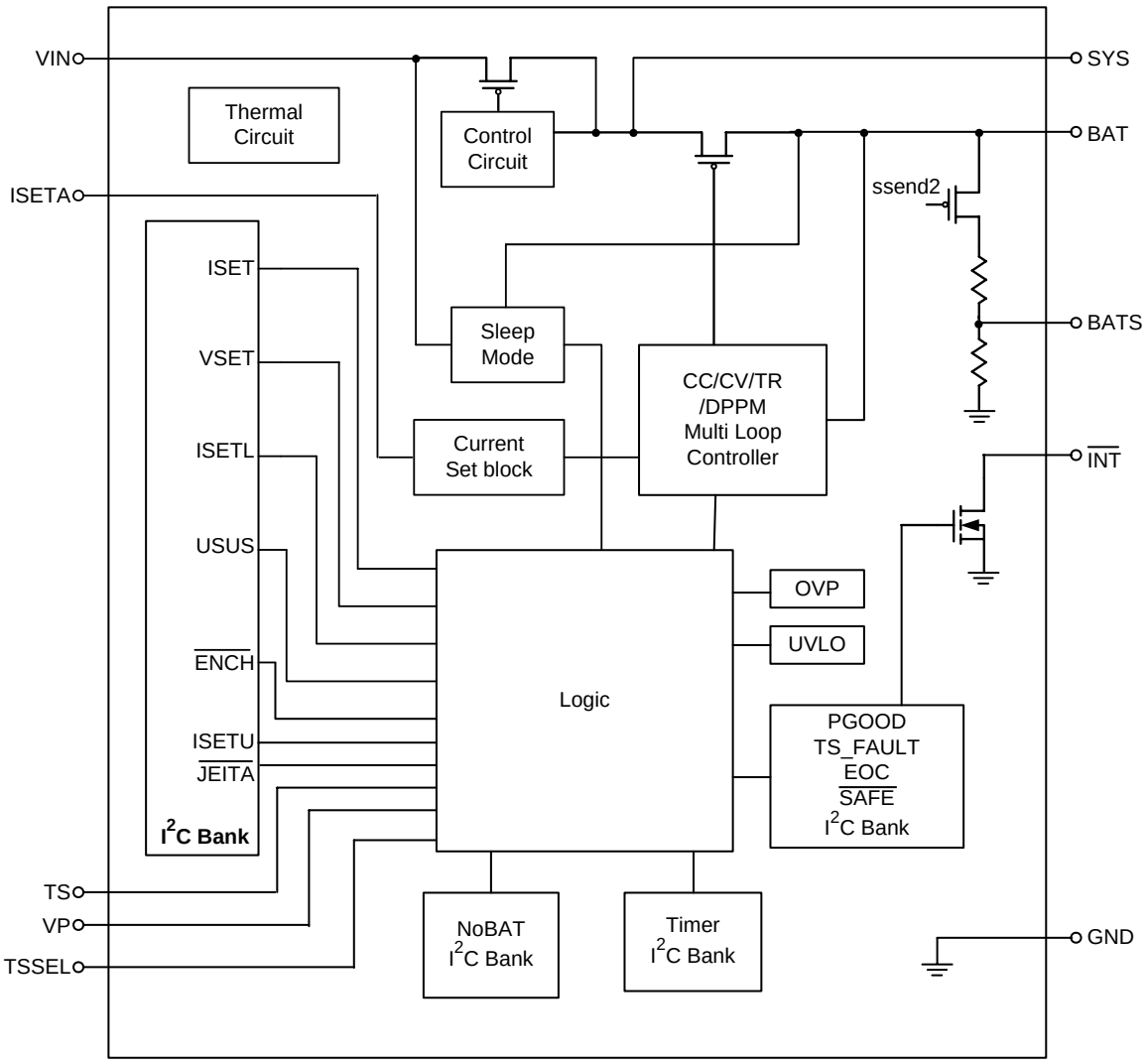
To be continued

Pin No.	Pin Name	Pin Function
33, 34	BAT	Battery Charge Current Output.
35, 36	SYS	System Connect Pin. Connect this pin to system with a minimum 10μF ceramic capacitor to GND.
37	VIN	Supply Voltage Input.
38	RTCPWR	RTC Power Output.
39	PVD1	Power Output of CH1.
40	LX1	Switch Node of CH1.
41 (Exposed Pad)	GND	Ground. The exposed pad must be soldered to a large PCB and connected to GND for maximum thermal dissipation.

Function Block Diagram



Charger Function Block Diagram



Absolute Maximum Ratings (Note 1)

- Battery Input Voltage, BAT ---------- –0.3V to 6V
- Supply Voltage, VDDM ---------- –0.3V to 6V
- Supply Input Voltage, VIN ---------- –0.3V to 28V
- BATS, $\overline{INT}$ ---------- –0.3V to 28V
- Other Pins ---------- –0.3V to 6V
- Power Switch (DC) :
  VOUT6 ---------- –10V to 0.3V
  LX1, LX2, LX3, LX4 ---------- –0.3V to 6V
  PVD5, LX5 ---------- –0.3V to 24V
  PVD7, LX7 ---------- –0.3V to 17V
  LX6 ---------- (PVD6 – 16V) to (PVD6 + 0.3V)
- $\overline{INT}$ Continuous Current ---------- 20mA
- BAT Continuous Current (total in two pins) (Note 2) ---------- 2.5A
- Power Dissipation, P_D @ T_A = 25°C
  WQFN-40L 5x5 ---------- 2.778W
- Package Thermal Resistance (Note 3)
  WQFN-40L 5x5, θ_{JA} ---------- 36°C/W
  WQFN-40L 5x5, θ_{JC} ---------- 7°C/W
- Junction Temperature ---------- 150°C
- Lead Temperature (Soldering, 10 sec.) ---------- 260°C
- Storage Temperature Range ---------- –65°C to 125°C
- ESD Susceptibility (Note 4)
  HBM (Human Body Mode) ---------- 2kV
  MM (Machine Mode) ---------- 200V

Recommended Operating Conditions (Note 5)

- Supply Voltage, VDDM ---------- 2.7V to 5.5V
- Supply Input Voltage, VIN (ISETL = 1) ---------- 4.4V to 6V
- Supply Input Voltage, VIN (ISETL = 0) ---------- 4.5V to 6V
- Junction Temperature Range ---------- –40°C to 125°C
- Ambient Temperature Range ---------- –40°C to 85°C

Electrical Characteristics

Power Converter Unit : (V_{DDM} = 4.2V, T_A = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Supply Voltage						
SYS Startup Voltage for PMU	V_{ST}		1.5	--	--	V
SYS UVLO (Hysteresis Low)			--	1.3	--	V
SYS UVLO Hysteresis (Gap)			--	0.2	--	V

To be continued

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
VDDM Over Voltage Protection (OVP) (Hysteresis High)			5.82	6.0	6.18	V
VDDM OVP Hysteresis (Gap)			--	–0.25	--	V
VDDM UVLO (Hysteresis High)			2.2	2.4	2.6	V
VDDM UVLO Hysteresis (Gap)			--	0.3	--	V
Supply Current						
Shutdown Supply Current	I_{OFF}	All Channels are Off, V_{EN1234} = 0V, V_{BAT} = 4.2V	--	10	20	µA
CH1 (Sync-Step-Up) Supply Current into VDDM	I_{Q1}	No Switching, V_{EN1234} = 3.3V	--	--	800	µA
CH2 (Syn-Step-Down) Supply Current into VDDM	I_{Q2}	No Switching, V_{EN1234} = 3.3V	--	--	800	µA
CH3 (Syn-Step-Down) Supply Current into VDDM	I_{Q3}	No Switching, V_{EN1234} = 3.3V	--	--	800	µA
CH4 (Syn-Step-Down) Supply Current into VDDM	I_{Q4}	No Switching, V_{EN1234} = 3.3V	--	--	800	µA
CH5 (Syn-Step-Up) Supply Current into VDDM	I_{Q5}	Non Switching, EN56 = 1	--	--	800	µA
CH6 (Inverting) Supply Current into VDDM	I_{Q6}	No Switching, EN56 = 1	--	--	800	µA
CH7 (WLED) in Step-Up Mode Supply Current into VDDM	I_{Q7b}	No Switching, EN7_DIM7 [4:0] = 31, MOD7 = 1	--	--	800	µA
CH7 (WLED) in Current Source mode Supply Current into VDDM	I_{Q7c}	EN7_DIM7 [4:0] = 31, MOD7 = 0	--	--	800	µA
Oscillator						
CH1, 2, 3, 4 Operation Frequency	f_{OSC}		1800	2000	2200	kHz
CH5, 6, 7 Operation Frequency	f_{OSC2}	CH7 in Step-Up Mode	900	1000	1100	kHz
CH1 Maximum Duty Cycle (Step-Up)		V_{FB1} = 0.75V	80	83	86	%
CH2 Maximum Duty Cycle (Step-Down)		V_{FB2} = 0.75V	--	--	100	%
CH3 Maximum Duty Cycle (Step-Down)		V_{FB3} = 0.75V	--	--	100	%
CH4 Maximum Duty Cycle (Step-Down)		V_{FB4} = 0.75V	--	--	100	%
CH5 Maximum Duty Cycle (Step-Up)		V_{FB5} = 1.15V	91	93	97	%
CH6 Maximum Duty Cycle (Inverting)		V_{FB6} = 0.7V	91	93	97	%
CH7 Maximum Duty Cycle (Step-Up)		V_{FB7} = 0.15V	91	93	97	%
Feedback, Output Regulation Voltage, and Output Regulation Current						
Feedback Regulation Voltage @ FB1, FB2, FB3, FB4			0.788	0.8	0.812	V
Feedback Regulation Voltage @ FB5			1.237	1.25	1.263	V
Feedback Regulation Voltage @ FB6 (Inverting)			0.58	0.6	0.62	V
Feedback Regulation Voltage @ FB7 (Step-Up mode and current source mode)		EN7_DIM7 [4:0] = 31	0.237	0.25	0.263	V

To be continued

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Reference						
VREF Output Voltage	V_{REF}		1.77	1.8	1.83	V
(VREF-FB6) Regulation Voltage			1.182	1.2	1.218	V
VREF Load Regulation		0μA < IREF < 200μA	--	--	10	mV
Power Switch						
CH1 On Resistance of MOSFET		P-MOSFET, V_{PVD1} = 3.3V	--	200	300	mΩ
		N-MOSFET, V_{PVD1} = 3.3V	--	150	250	
CH1 Current Limitation (Step-Up)			2.2	3	4	A
CH2 On Resistance of MOSFET		P-MOSFET, V_{PVD2} = 3.3V	--	200	300	mΩ
		N-MOSFET, V_{PVD2} = 3.3V	--	150	250	
CH2 Current Limitation (Step-Down)			1.4	1.8	2.2	A
CH3 On Resistance of MOSFET		P-MOSFET, V_{PVD3} = 3.3V	--	300	400	mΩ
		N-MOSFET, V_{PVD3} = 3.3V	--	300	400	
CH3 Current Limitation (Step-Down)			1.2	1.6	2	A
CH4 On Resistance of MOSFET		P-MOSFET, V_{PVD4} = 3.3V	--	300	400	mΩ
		N-MOSFET, V_{PVD4} = 3.3V	--	300	400	
CH4 Current Limitation (Step-Down)			1.2	1.6	2	A
CH5 On Resistance of P-MOSFET		V_{PVD5} = 16V	--	1.1	1.5	Ω
CH5 On Resistance of N-MOSFET		V_{DDM} = 3.3V	--	0.6	0.8	Ω
CH5 Current Limitation (Step-Up)		N-MOSFET	0.9	1.2	1.6	A
CH6 On Resistance of MOSFET		P-MOSFET, V_{PVD6} = 3.3V	--	0.5	0.7	Ω
CH6 Current Limitation (Inverting)		P-MOSFET	1	1.5	2	A
CH7 On Resistance of P-MOSFET		V_{PVD7} = 10V	--	2.0	3.0	Ω
CH7 On Resistance of N-MOSFET		V_{DDM} = 3.3V	--	0.9	1.1	Ω
CH7 Current Limitation (Step-Up)		N-MOSFET	0.6	0.8	1	A
Protection						
Over Voltage Protection of PVD1			5.82	6.0	6.18	V
Over Voltage Protection of PVD5			20	22	24	V
Over Voltage Protection of VOUT6			--	–13	--	V
Over Voltage Protection of PVD7 (Step-Up mode)			14.2	15	16	V
CH1 Step-Up Under Voltage Protection of PVD1			--	V_{SYS} –0.8V	--	V
CH1/2/3/4 Under Voltage Protection		At V_{FBx} < 0.4V after soft-start ends	0.35	0.4	0.45	V
CH5 Under Voltage Protection		At V_{FB5} < 0.6V after soft-start ends	0.5	0.6	0.7	V
CH6 Under Voltage Protection		At V_{FB6} > 1.2V after soft-start end	1.1	1.2	1.3	V
CH1/2/3/4 Overload Protection		At V_{FBx} < 0.72V after fault delay (100ms)	0.65	0.7	0.75	V
CH5 Overload Protection		At V_{FB5} < 1.1V after fault delay (100ms)	1.05	1.1	1.15	V
CH6 Overload Protection		At V_{FB6} > 0.74V after fault delay (100ms)	0.69	0.74	0.79	V
Protection Fault Delay			--	100	--	ms

To be continued

Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
Control							
EN1234, TSSEL Input Voltage Threshold	Logic-High			1.3	--	--	V
	Logic-Low			--	--	0.4	
EN1234, TSSEL Sink Current				--	1	6	μA
Thermal Protection							
Thermal Shutdown		T_{SD}		--	155	--	°C
Thermal Shutdown Hysteresis		ΔT_{SD}		--	20	--	°C
RTC LDO							
Standby Current			V_{DDM} = 4.2V	--	3	6	μA
V_{OUT} (RTCPWR)			I_{OUT} = 0mA, V_{DDM} = 4.2V	3.23	3.3	3.37	V
Max Output Current (Current Limit)			V_{DDM} = 4.2V	60	130	200	mA
Dropout Voltage			I_{OUT} = 50mA	--	--	1000	mV
			I_{OUT} = 10mA	--	--	150	
			I_{OUT} = 3mA	--	--	60	
WAKE Up Detector							
WAKE Impulse High Duration		t_{WAKEUP}	VIN or BAT plug in, RTCPWR = 3.3V	--	55	--	ms
WAKE Output	High Level	V_{WAKE_H}	Source Current 0.5mA, RTCPWR = 3.3V	--	RTCPWR – 0.3	RTCPWR	V
	Low Level	V_{WAKE_L}	Sink Current –0.5mA, RTCPWR = 3.3	0	0.3	--	
VIN Threshold to Wake Up				3.1	3.3	3.5	V
BAT Threshold to Wake Up				--	2.7	--	V
BAT Threshold Hysteresis to Wake Up				--	150	--	mV

Charger Unit : (V_{IN} = 5V, V_{BAT} = 4V, T_A = 25°C, unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Supply Input						
VIN Under Voltage Lockout Threshold	V_{UVLO}	V_{IN} = 0V to 4V	3.1	3.3	3.5	V
VIN Under Voltage Lockout Hysteresis	ΔV_{UVLO}	V_{IN} = 4V to 0V	--	240	--	mV
VIN Supply Current	I_{SUPPLY}	I_{SYS} = I_{BAT} = 0mA, $\overline{ENCH}$ = 0 (V_{BAT} > V_{REGx})	--	1	2	mA
		I_{SYS} = I_{BAT} = 0mA, $\overline{ENCH}$ = 1 (V_{BAT} > V_{REGx})	--	0.8	1.5	
VIN Suspend Current	I_{USUS}	V_{IN} = 5V, USUS = 1	--	195	300	μA
VIN – BAT VOS Rising	V_{OS_H}		--	200	300	mV
VIN – BAT VOS Falling	V_{OS_L}		10	50	--	mV
Voltage Regulation						
System Regulation Voltage	V_{SYS}	I_{SYS} = 800mA	4.3	4.4	4.5	V
Battery Regulation Voltage	V_{REG1}	0 to 85°C, Loading = 20mA, when VSET = 1	4.16	4.2	4.23	V
Battery Regulation Voltage	V_{REG2}	0 to 85°C, Loading = 20mA, when VSET = 0	4.01	4.05	4.08	V

To be continued

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
APPM Regulation Voltage	ΔV_{APPM}	$V_{SYS} - V_{APPM}$	120	200	280	mV
DPM Regulation Voltage	V_{DPM}	ISETL = 0	4.3	4.4	4.5	V
VIN to SYS MOSFET On-Resistance		I_{VIN} = 1000mA	--	0.2	0.35	Ω
BAT to SYS MOSFET On-Resistance		V_{BAT} = 4.2V, I_{SYS} = 1A	--	0.05	0.1	Ω
Re-Charge Threshold	ΔV_{REGCHG}	Battery Regulation – Recharge Level	60	100	140	mV
BATS Divider Ratio		V_{BAT} = 4.2V	58.3	59.8	61.3	%
Current Regulation						
ISETA Set Voltage (Fast Charge Phase)	V_{ISETA}	V_{BAT} = 4V, R_{ISETA} = 1kΩ	--	2	--	V
Charge Current Setting Range	I_{CHG}		100	--	1200	mA
Charge Current Accuracy1	I_{CHG1}	V_{BAT} = 4V, R_{ISETA} = 1kΩ ISET = 1	570	600	630	mA
Charge Current Accuracy2	I_{CHG2}	V_{BAT} = 3.8V, R_{ISETA} = 1kΩ, ISET = 0	285	300	315	mA
VIN Current Limit	I_{VIN}	ISETL = 1 (1.5A Mode)	1.2	1.5	1.8	A
		ISETL = 0, ISETU = 1 (500mA Mode)	450	475	500	mA
		ISETL = 0, ISETU = 0 (100mA Mode)	90	95	100	
Pre-Charge						
BAT Pre-Charge Threshold	V_{PRECH}	BAT Falling	2.7	2.8	2.9	V
BAT Pre-Charge Threshold Hysteresis	ΔV_{PRECH}		--	200	--	mV
Pre-Charge Current	I_{CHG_PRE}	V_{BAT} = 2V	5	10	15	%
Charge Termination Detection						
Termination Current Ratio to Fast Charge (Except USB 100 Mode)	I_{TERM}	ISETL = 0, ISETU = 1 ISETL = 1, ISETU = X	5	10	15	%
Termination Current Ratio to Fast Charge (USB100 Mode)	I_{TERM2}	ISETL = 0, ISETU = 0	--	3.3	--	%
Login Input/Output						
$\overline{INT}$ Pull Down Voltage	$V_{\overline{INT}}$	$I_{\overline{INT}}$ = 5mA	--	200	--	mV
Protection						
Thermal Regulation	T_{REG}		--	125	--	°C
Thermal Shutdown Temperature	T_{SD}		--	155	--	°C
Thermal Shutdown Hysteresis	ΔT_{SD}		--	20	--	°C
Over Voltage Protection	V_{OVP}	VIN Rising	6.25	6.5	6.75	V
Over Voltage Protection Hysteresis	ΔV_{OVP}	V_{IN} = 7V to 5V, $V_{OVP} - \Delta V_{OVP}$	--	100	--	mV
Output Short Circuit Detection Threshold	V_{SHORT}	$V_{BAT} - V_{SYS}$	--	300	--	mV
Battery Installation Detection Threshold at TS		EN1234 = H	--	90	--	% of VP
Time						
Pre-Charge Fault Time	t_{PCHG}	TIMER [3:0] = 0100, (1/8 x t_{FCHG})	1800	2250	2700	s
Fast Charge Fault Time	t_{FCHG}	TIMER [3:0] = 0100	14400	18000	21600	s

To be continued

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
PGOOD Deglitch Time	t_{PGOOD}	Time measured from VIN : 0 to 5V 1μs rise-time to PGOOD = 1 in I^2C Register	--	1	--	s
Input Over Voltage Blanking Time	t_{OVP}		--	50	--	μs
Pre-Charge to Fast-Charge Deglitch Time	t_{PF}		--	25	--	ms
Fast-Charge to Pre-Charge Deglitch Time	t_{FP}		--	25	--	ms
Termination Deglitch Time	t_{TERMI}		--	25	--	ms
Recharge Deglitch Time	t_{RECHG}		--	100	--	ms
Input Power Loss to SYS LDO Turn-Off Delay Time	t_{NO_IN}		--	25	--	ms
Pack Temperature Fault Detection Deglitch Time	t_{TS}		--	25	--	ms
Short Circuit Deglitch Time	t_{SHORT}		--	250	--	μs
Short Circuit Recovery Time	$t_{SHORT-R}$		--	64	--	ms
Other						
VP Regulation Voltage	V_{VP}	V_{DDM} = 4.2V	3.234	3.3	3.366	V
VP Load Regulation	V_{VP}	VP Source Out 2mA	--	--	-0.1	V
VP Under Voltage Lockout Threshold		Falling Threshold	--	0.8	--	V
TS Battery Detect Threshold	V_{TS}		2.75	2.85	2.95	V
NTC						
Low Temperature Trip Point (0°C)	V_{COLD}	Rising Threshold when TSSEL = L (100k NTC)	73	74	75	% of VP
		Rising Threshold when TSSEL = H (10k NTC)	59	60	61	
Low Temperature Trip Point Hysteresis (near 0°C)	ΔV_{COLD}		--	1	--	% of VP
High Temperature Trip Point (60°C)	V_{HOT}	Falling Threshold when TSSEL = L	27	28	29	% of VP
		Falling Threshold when TSSEL = H	37	38	39	
High Temperature Trip Point Hysteresis (near 60°C)	ΔV_{HOT}		--	1	--	% of VP
Low Temperature Trip Point (10°C) for JEITA		Rising Threshold when TSSEL = L (100k NTC)	63	64	65	% of VP
		Rising Threshold when TSSEL = H (10k NTC)	53	54	55	
Low Temperature Trip Point Hysteresis (near 10°C) for JEITA			--	1	--	% of VP
High Temperature Trip Point (45°C) for JEITA		Falling Threshold when TSSEL = L	34	35	36	% of VP
		Falling Threshold when TSSEL = H	39	40	41	
High Temperature Trip Point Hysteresis (near 45°C) for JEITA			--	1	--	% of VP

(V_{DDM} = 3.3V, T_A = 25°C, unless otherwise specified)

Parameter		Symbol	Test Conditions	Min	Typ	Max	Unit
Logic Inputs (SDA SCL)							
SDA, SCL Input Threshold Voltage	Logic-High			2.0	--	--	V
	Logic-Low			--	--	0.8	
I²C Timing Characteristics							
SCL Clock Rate		f_{SCL}	V_{DDM} = 3.3V	--	--	400	kHz
Hold Time (Repeated) START Condition. After this period, the first clock pulse is generated		$t_{HD;STA}$		0.6	--	--	µs
LOW Period of SCL Clock		t_{LOW}		1.3	--	--	µs
HIGH Period of SCL Clock		t_{HIGH}		0.6	--	--	µs
Set-up Time for Repeated START Condition		$t_{SU;STA}$		0.6	--	--	µs
Data Hold Time		$t_{HD;DAT}$		0	--	0.9	µs
Data Set-up Time		$t_{SU;DAT}$		100	--	--	ns
Set-up Time for STOP Condition		$t_{SU;STO}$		0.6	--	--	µs
Bus Free Time between a STOP and START Condition		t_{BUF}		1.3	--	--	µs
Rise Time of both SDA and SCL Signals		t_R		20	--	300	ns
Fall Time of both SDA and SCL Signals		t_F		20	--	300	ns
SDA and SCL Output Low Sink Current		I_{OL}	SDA or SCL Voltage = 0.4V	2	--	--	mA

Note 1. Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

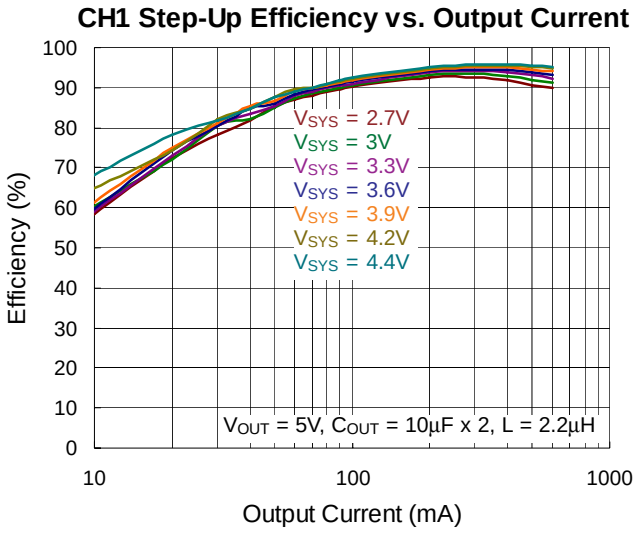
Note 2. Guaranteed by design.

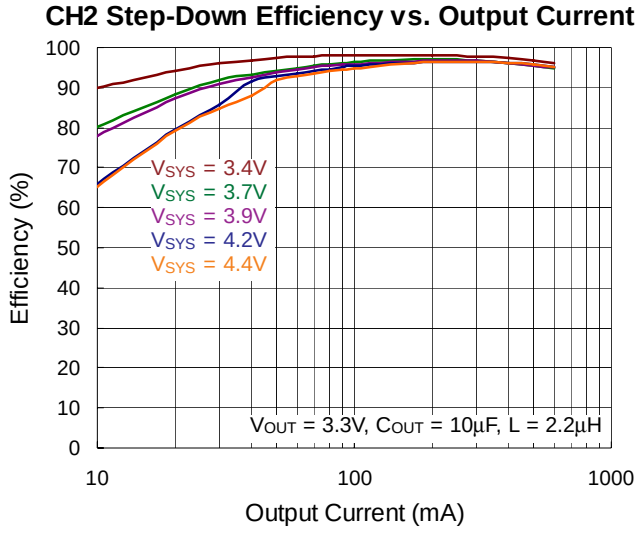
Note 3. θ_{JA} is measured in natural convection at T_A = 25°C on a high-effective thermal conductivity four-layer test board of JEDEC 51-7 thermal measurement standard. The measurement case position of θ_{JC} is on the exposed pad of the package.

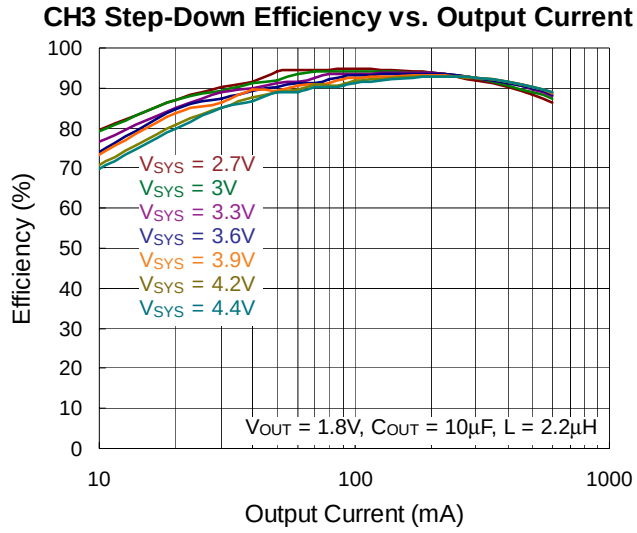
Note 4. Devices are ESD sensitive. Handling precaution is recommended.

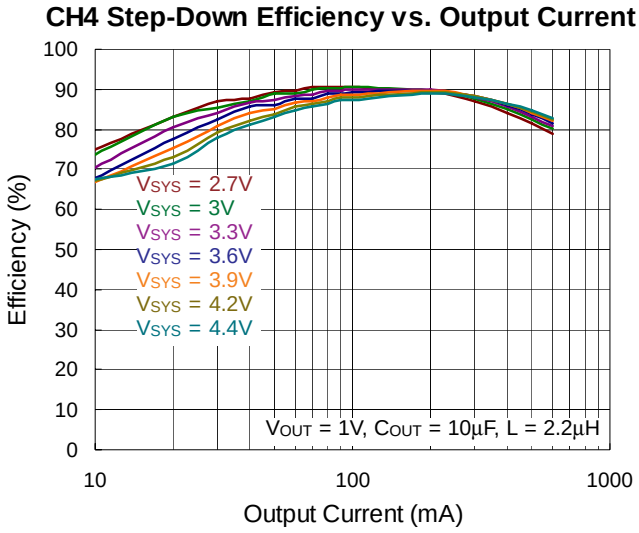
Note 5. The device is not guaranteed to function outside its operating conditions.

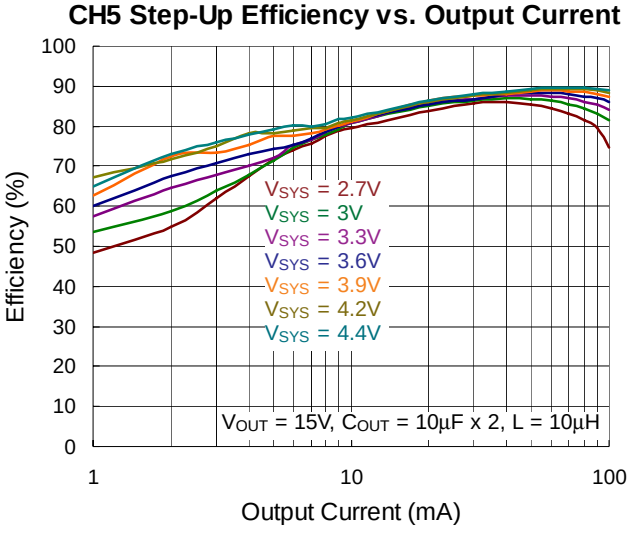
Typical Operating Characteristics

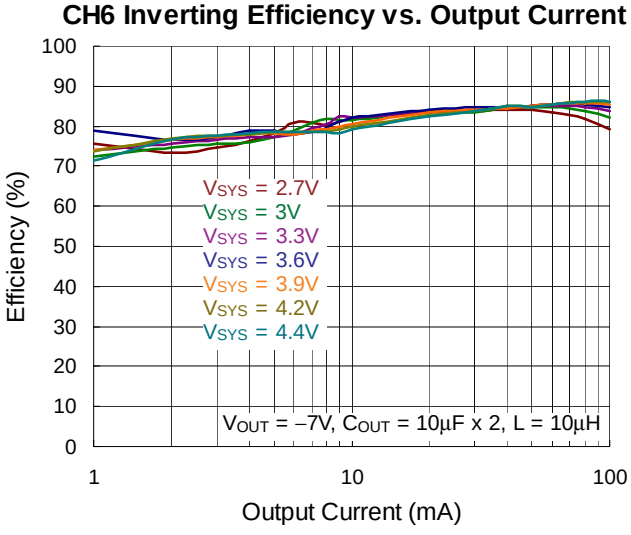




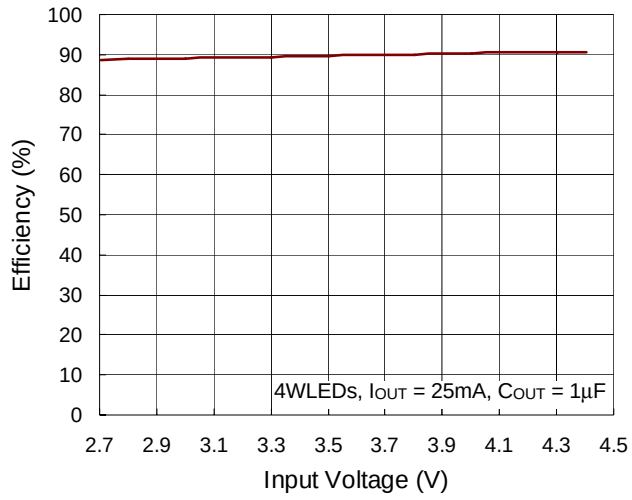




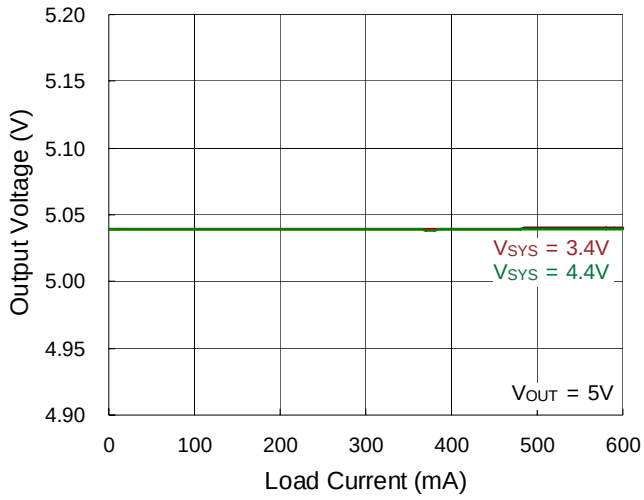




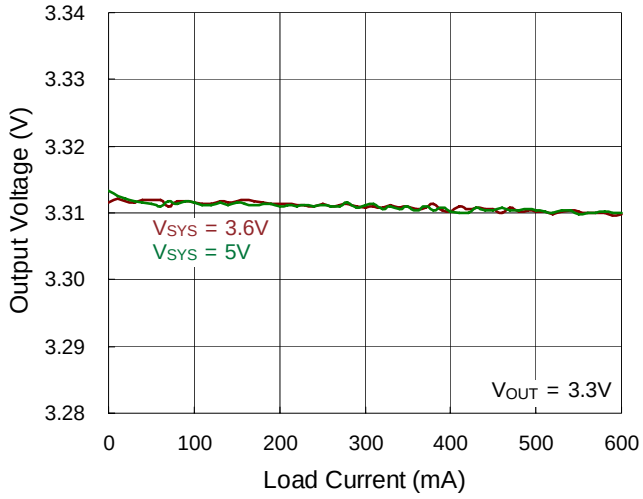
CH7 Efficiency vs. Input Voltage



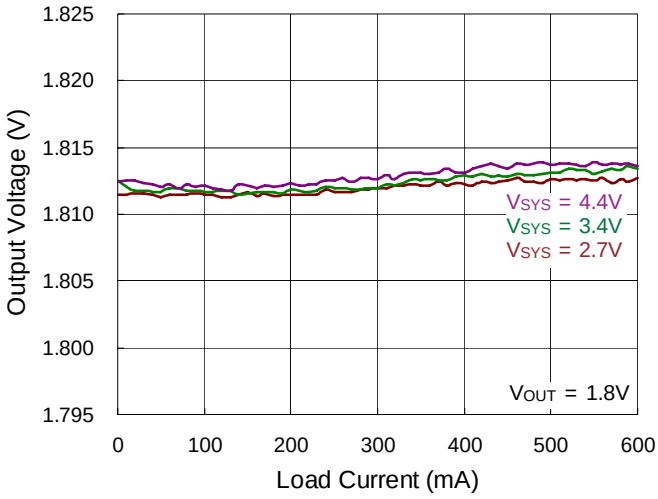
CH1 Step-Up Output Voltage vs. Output Current



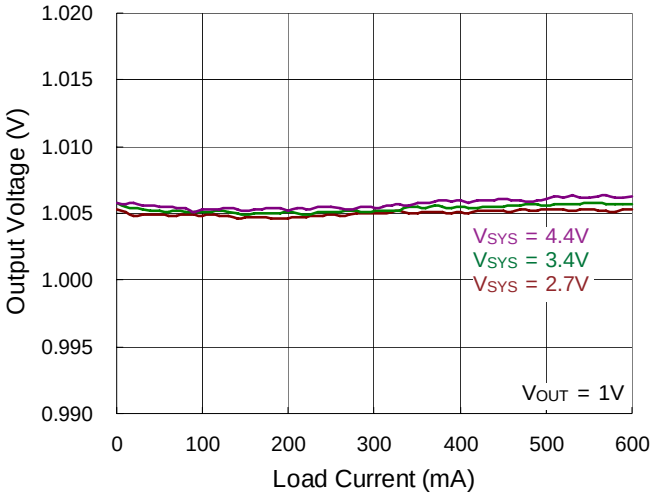
CH2 Step-Down Output Voltage vs. Output Current



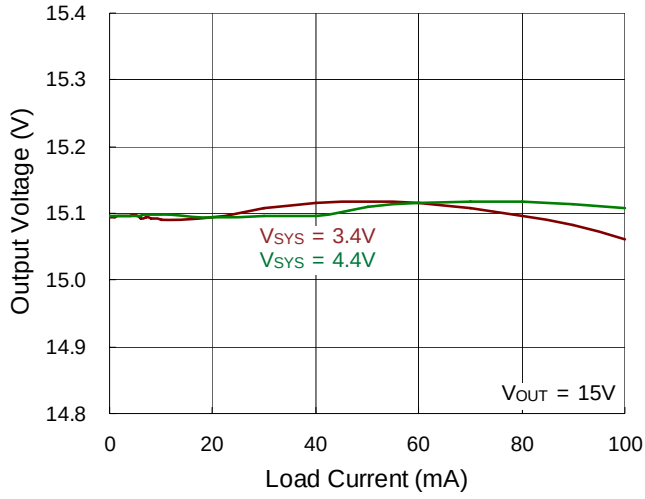
CH3 Step-Down Output Voltage vs. Output Current



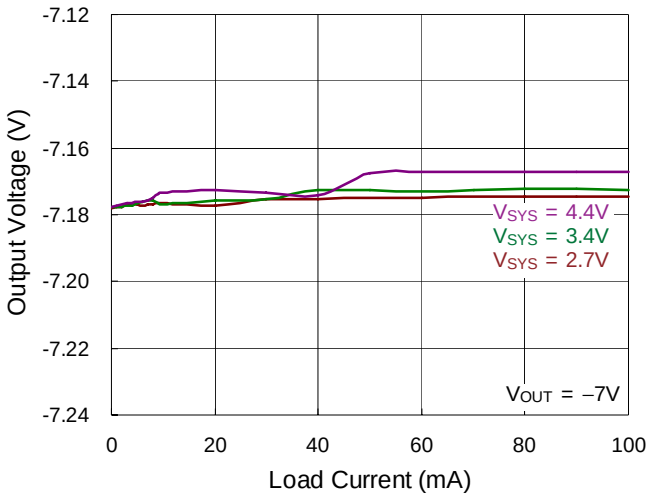
CH4 Step-Down Output Voltage vs. Output Current



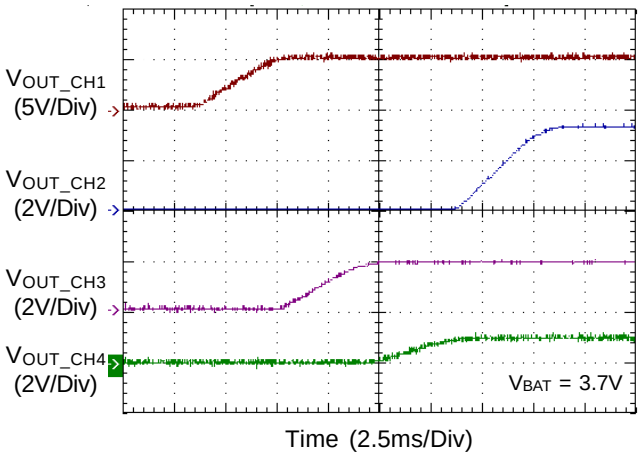
CH5 Step-Up Output Voltage vs. Output Current



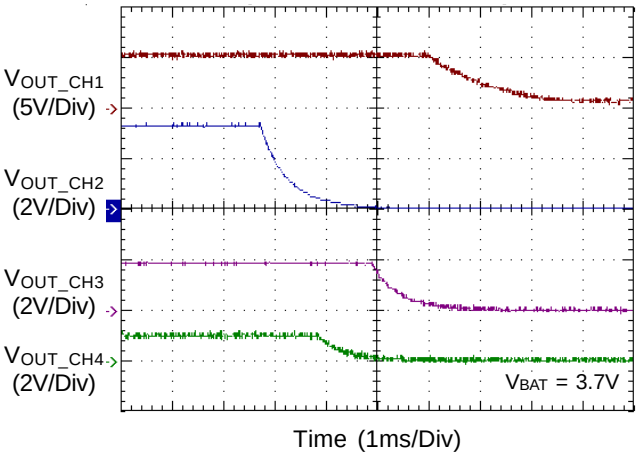
CH6 Inverting Output Voltage vs. Output Current



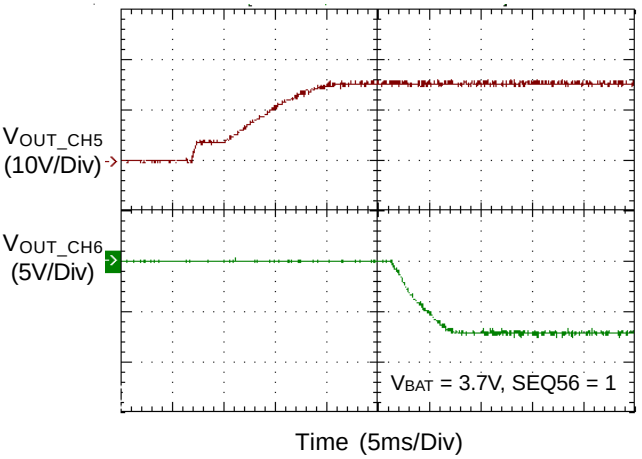
Power On



Power Off



Power On



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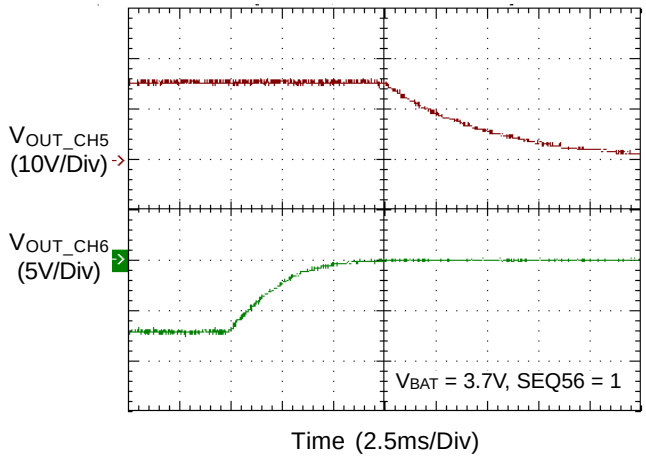

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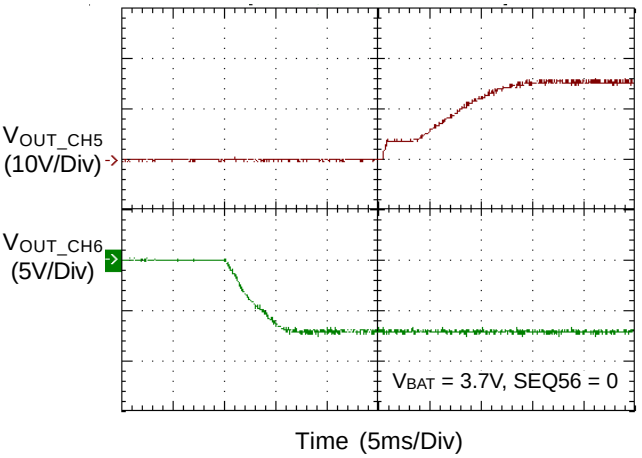

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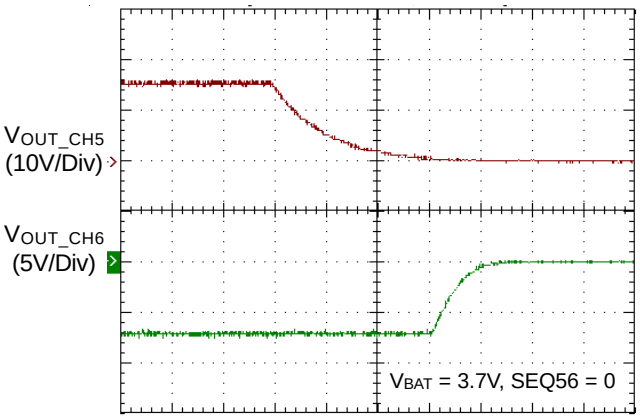
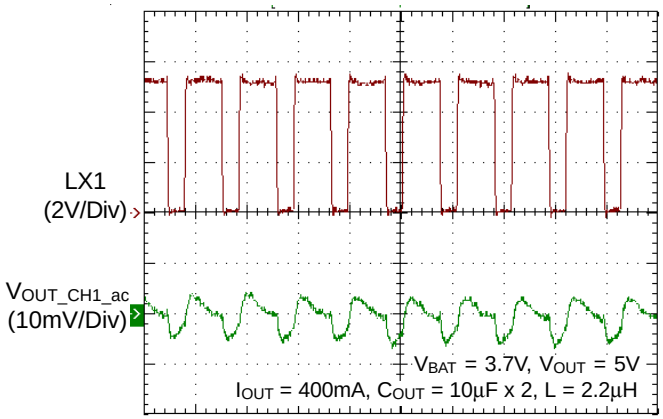


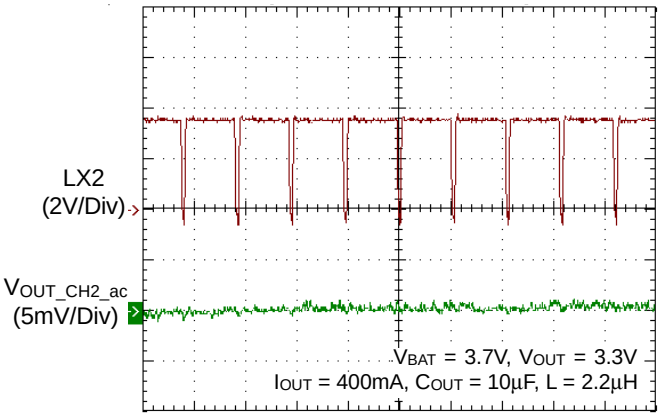
Time (5ms/Div)

CH1 Output Voltage Ripple



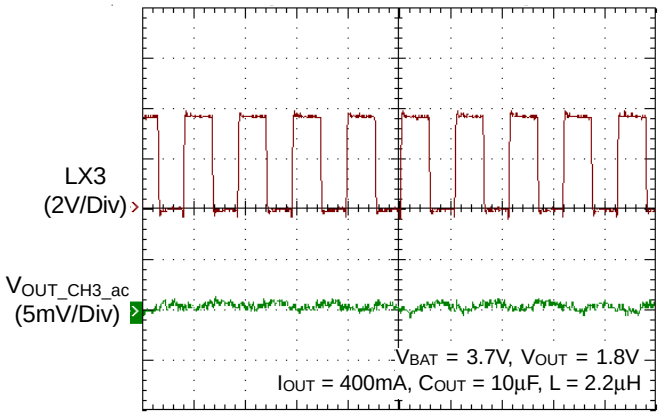
Time (500ns/Div)

CH2 Output Voltage Ripple



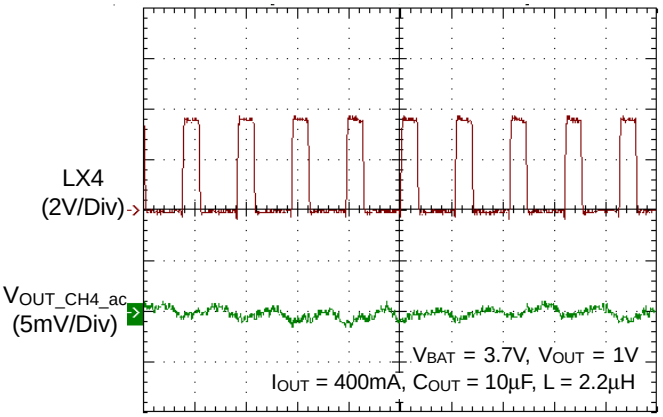
Time (500ns/Div)

CH3 Output Voltage Ripple



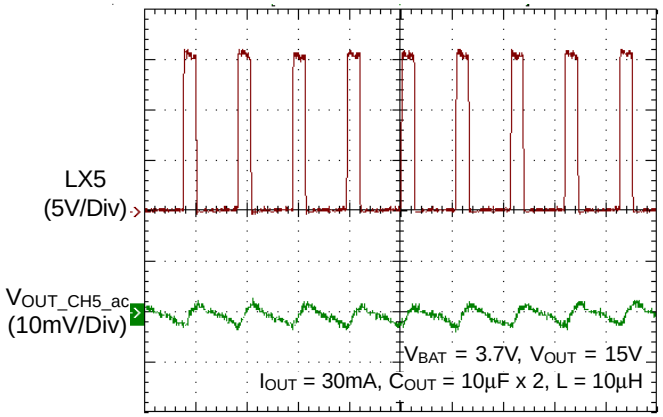
Time (500ns/Div)

CH4 Output Voltage Ripple



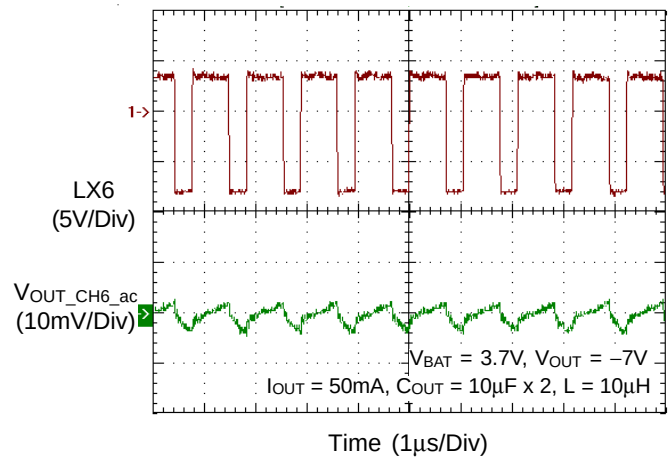
Time (500ns/Div)

CH5 Output Voltage Ripple

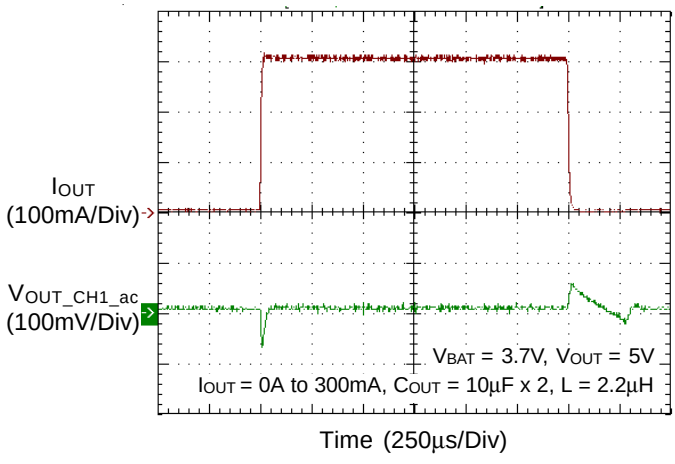


Time (1µs/Div)

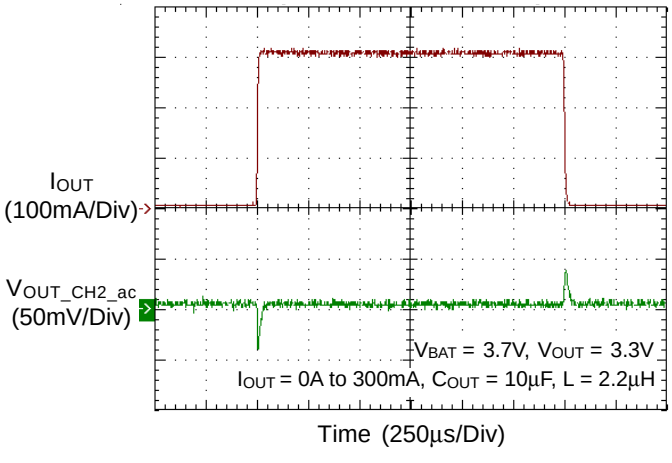
CH6 Output Voltage Ripple



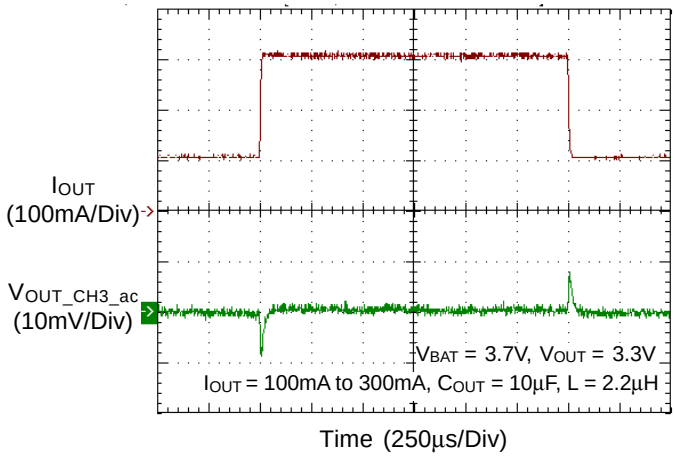
CH1 Load Transient Response



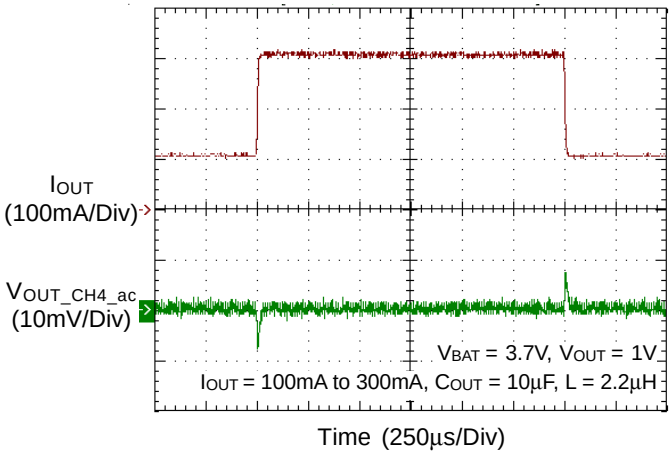
CH2 Load Transient Response



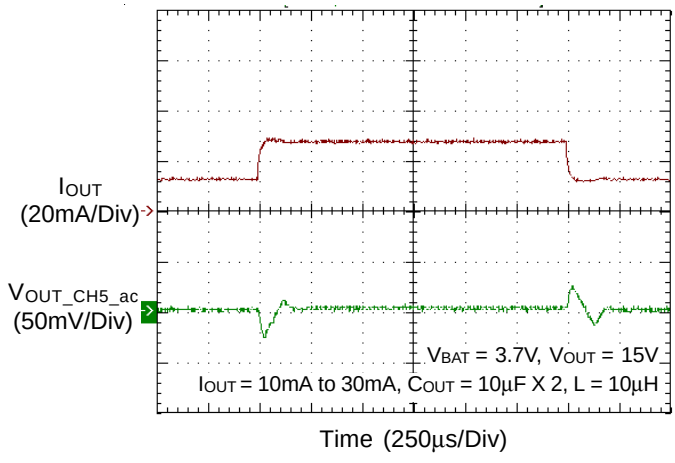
CH3 Load Transient Response



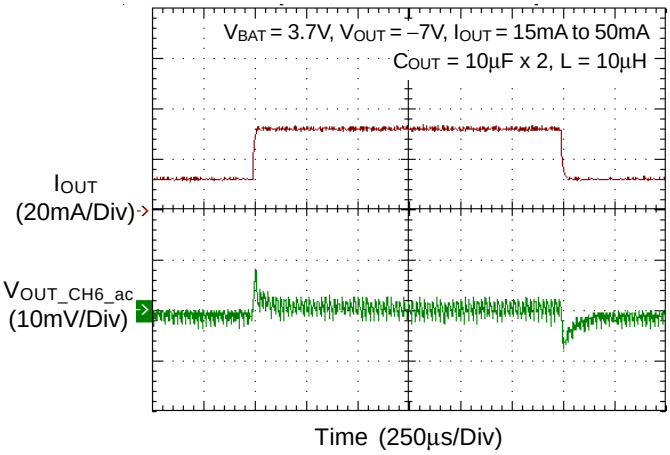
CH4 Load Transient Response



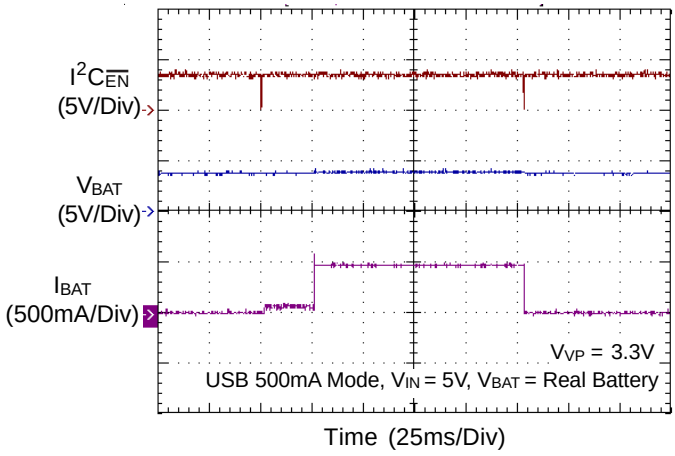
CH5 Load Transient Response



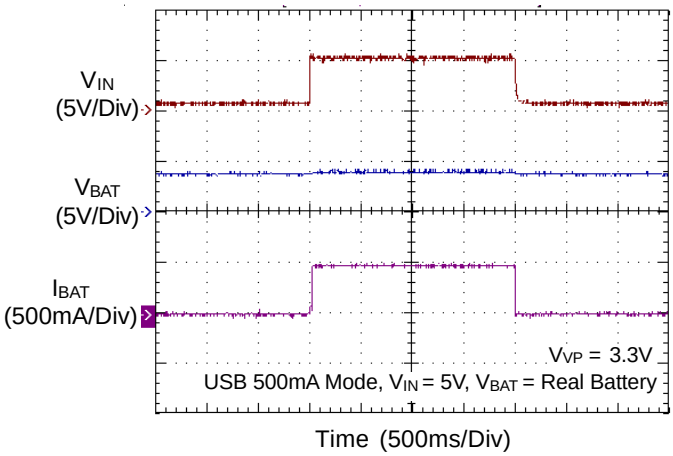
CH6 Load Transient Response



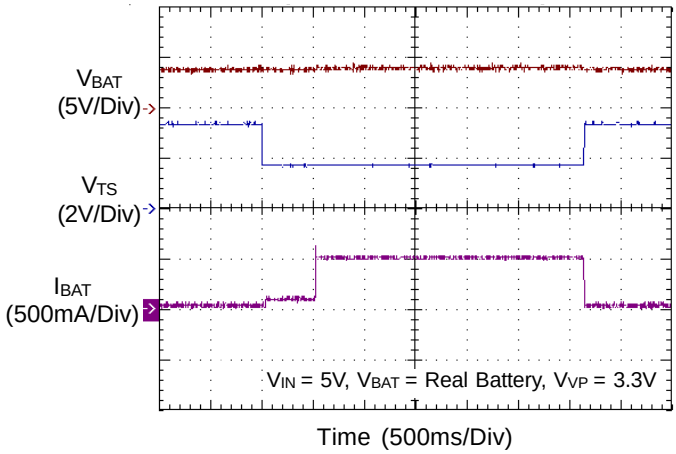
Charger On/Off Control from $\overline{ENCH}$



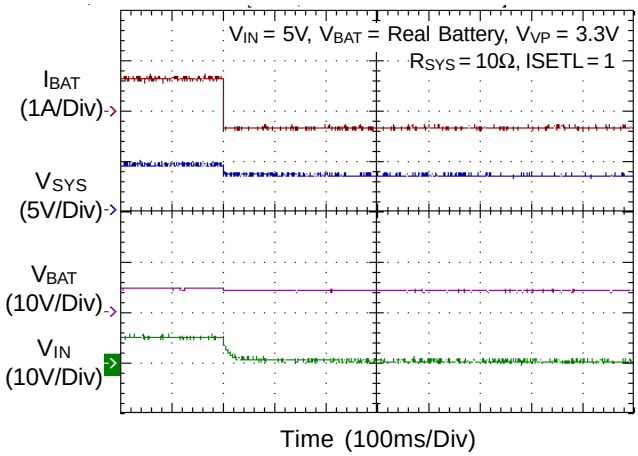
Charger On/Off Control from V_{IN}



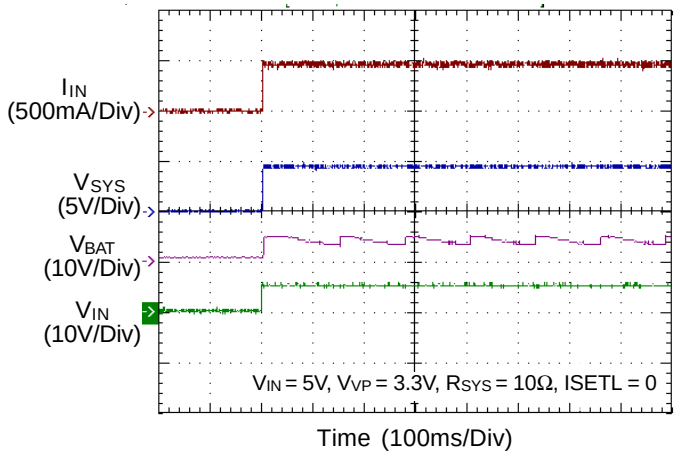
TS Inserted / Removed



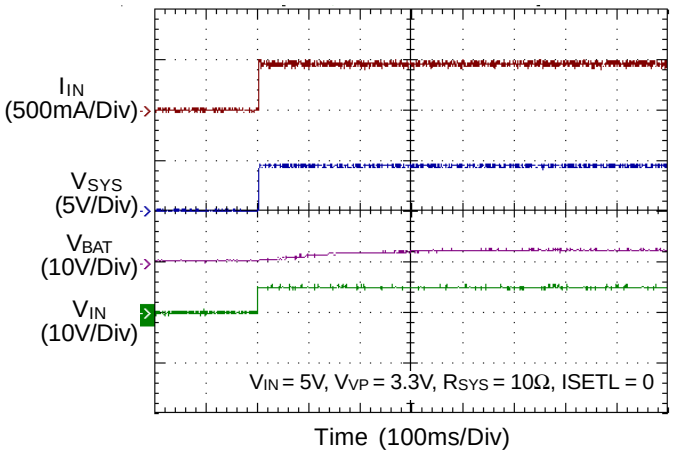
V_{IN} Removal



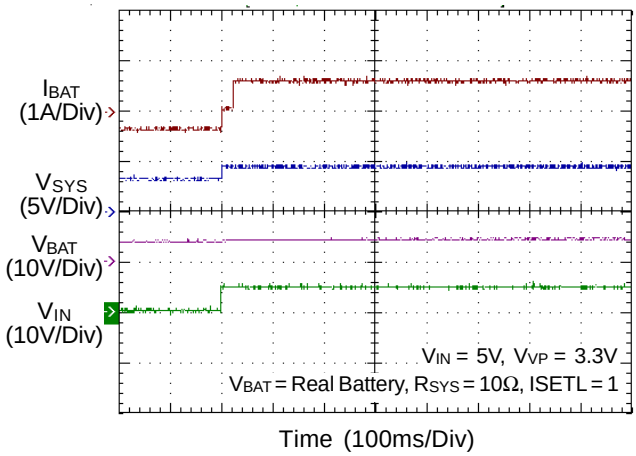
V_{IN} Hot-Plug with NTC/without Battery



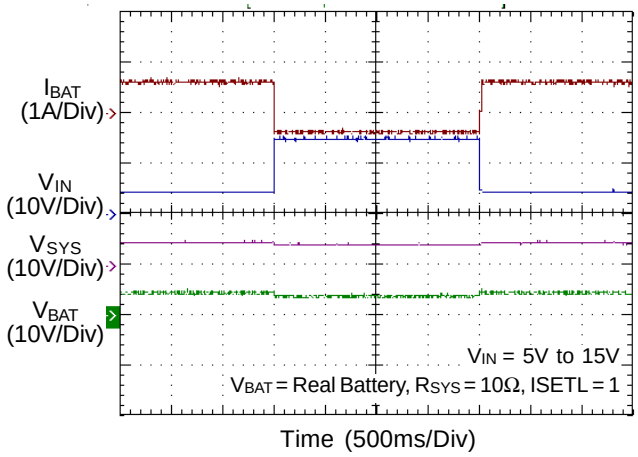
V_{IN} Hot-Plug without NTC/Battery



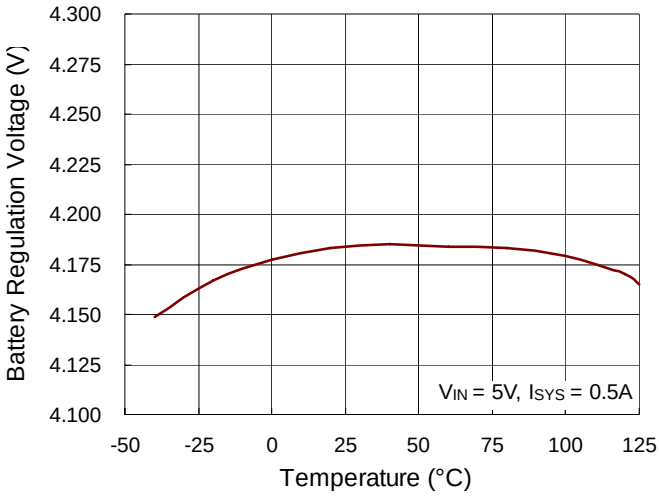
V_{IN} Hot-Plug with Battery



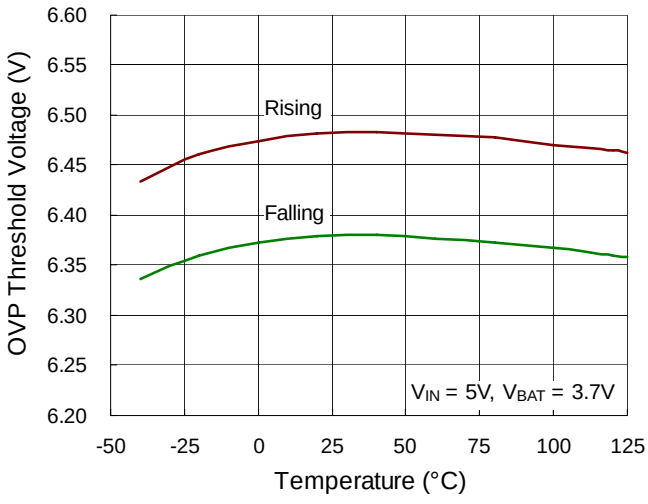
V_{IN} Over Voltage Protection



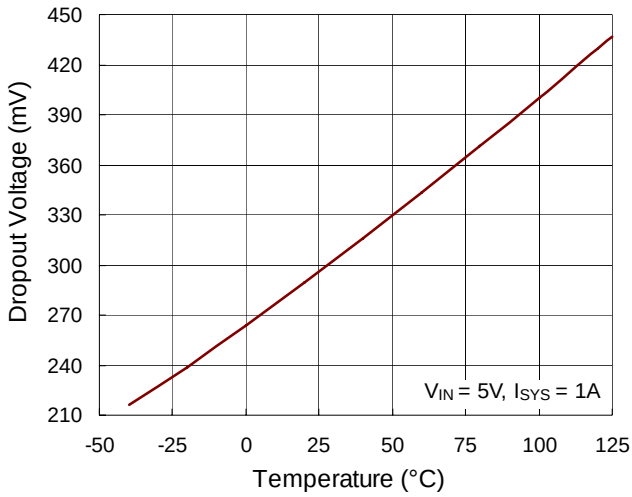
Battery Regulation Voltage vs. Temperature



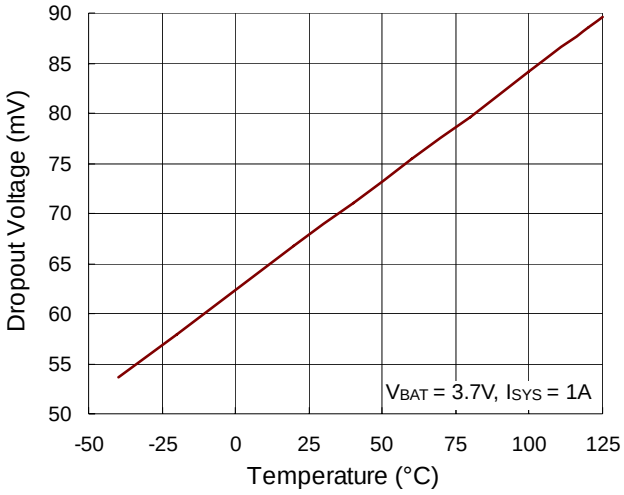
OVP Threshold Voltage vs. Temperature



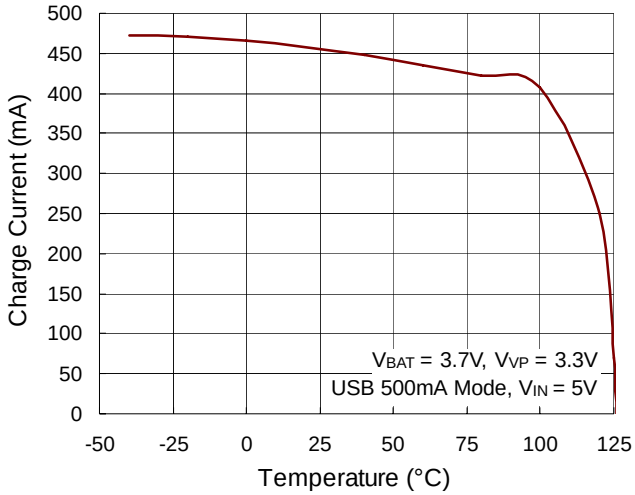
V_{IN} - V_{SYS} Dropout Voltage vs. Temperature



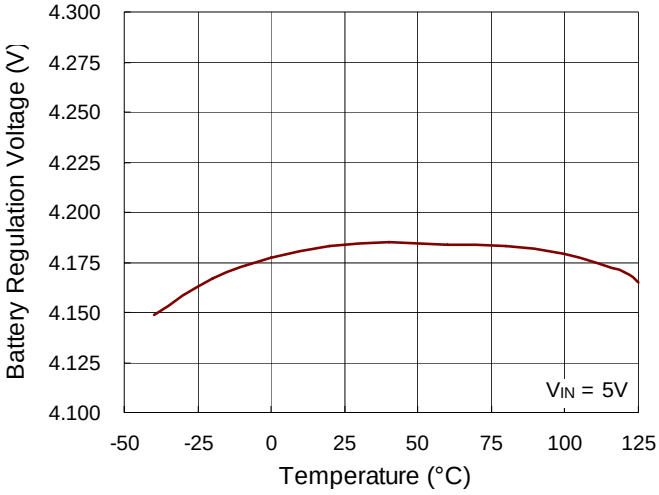
V_{BAT} - V_{SYS} Dropout Voltage vs. Temperature



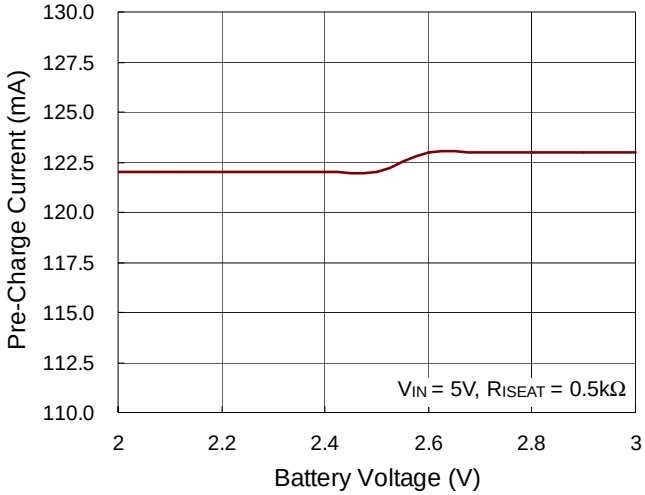
Charge Current vs. Temperature



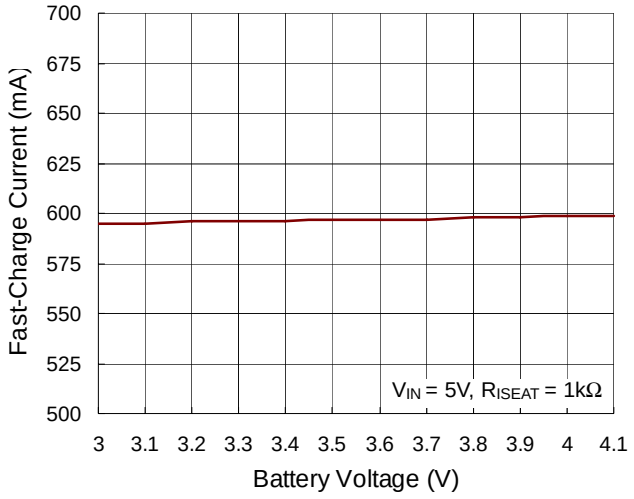
Battery Regulation Voltage vs. Temperature



Pre-Charge Current vs. Battery Voltage



Fast-Charge Current vs. Battery Voltage



Application Information

Power Converter Unit

The RT5002 is an integrated power system for digital still cameras and other small handheld devices. It includes six DC/DC converters as well as one WLED driver, one RTC LDO, and a fully integrated single-cell Li-ion battery charger ideal for portable applications.

CH1 : Step-up synchronous current mode DC/DC converter with internal power MOSFETs and compensation network. The P-MOSFET body can be controlled to disconnect the load. It is suitable for providing power to the motor.

CH2 to CH4 : Step-down synchronous current mode DC/DC converter with internal power MOSFETs and compensation network. These channels supply the power for I/O, DRAM, and core. They can be operated at 100% maximum duty cycle to extend battery operating voltage range. When the input voltage is close to the output voltage, the converter enters low dropout mode with low output ripple.

CH5 : High voltage step-up synchronous current mode DC/DC converter with internal power MOSFET and compensation network. The P-MOSFET body can be controlled to disconnect the load. This channel supplies the CCD+ bias.

CH6 : Asynchronous inverting current mode DC/DC converter with internal power MOSFET and compensation network. An external Schottky diode is required. This channel supplies the CCD– bias.

CH7 : WLED driver operating in either current source mode or synchronous step-up mode with internal power MOSFET and compensation network. The operation mode is determined via the I^2C interface. The P-MOSFET body in step-up mode can be controlled to disconnect the load.

CH1 to CH4 operate in PWM mode with 2MHz, while CH5 to CH7 operate in PWM mode with 1MHz switching frequency.

RTC_LDO : 3.3V output LDO with low quiescent current and reverse leakage prevention from output node.

Output Voltage Design Equation of CH1 to CH4 :

The output voltage can be set by the following equation :

$V_{OUT} = (1 + R_H / R_L) \times V_{FB}$

where VFB is 0.8V typically, R_H is R1, R3, R5, and R7 respectively for CH1 to 4, and R_L is R2, R4, R6, and R8 respectively for CH1 to 4.

Output Voltage Design Equation of CH5 :

The output voltage can be set by the following equation :

$V_{OUT_CH5} = (1 + R9 / R10) \times V_{FB5}$

where V_{FB5} is 1.25V typically.

Output Voltage Design Equation of CH6 :

The output voltage can be set by the following equation :

$V_{OUT_CH6} = -(R11 / R12) \times (1.2V) + 0.6V$

where R11 and R12 are the feedback resistors connected to FB6, 1.2V equals to ($V_{REF} - V_{FB6}$), and 0.6V is the typical value of V_{FB6}.

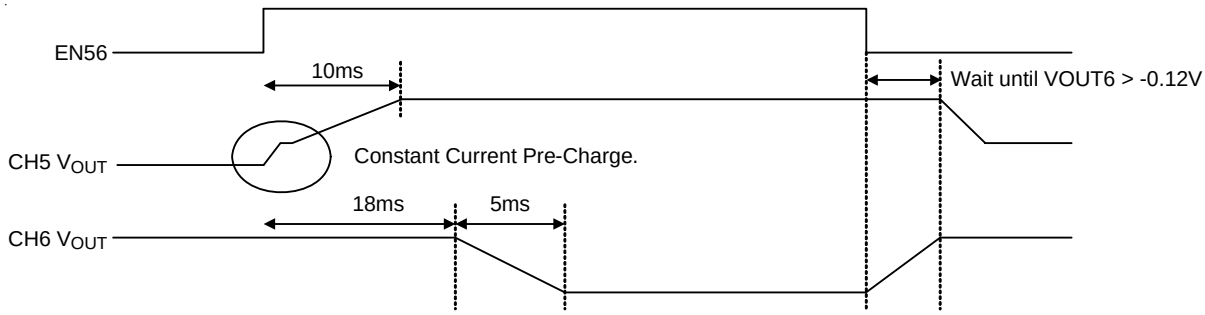
Reference Voltage

The RT5002 provides a precise 1.8V reference voltage, V_{REF}, with sourcing capability of 100μA. Connect a 0.1μF ceramic capacitor from the V_{REF} pin to GND. Reference voltage is enabled by I^2C register bit EN56 = 1. Furthermore, this reference voltage is internally pulled to GND at shutdown.

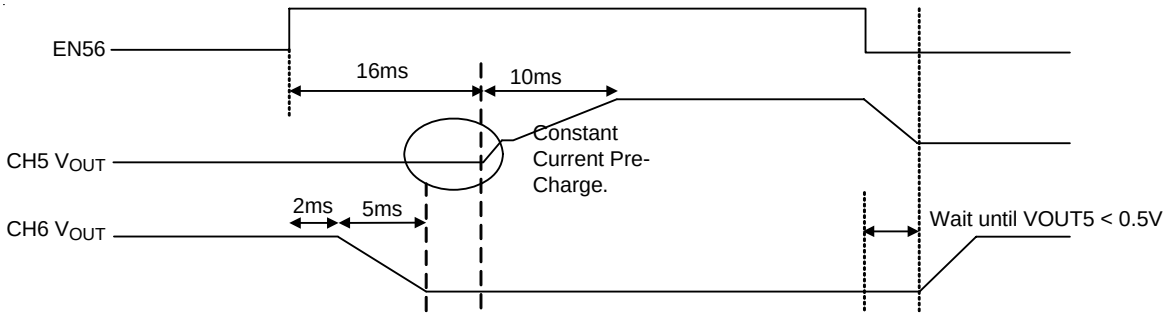
CH5 and CH6 Power Sequence :

CH5 and CH6 are enabled together via I^2C interface and their power on sequence can be chosen via I^2C register setting.

SEQ56 = 1



SEQ56 = 0



CH7 : WLED Driver

CH7 is a WLED driver that can operate in either current source mode or synchronous step-up mode, as determined by the I^{2}C interface. When CH7 works in current source mode, it sources an LED current out of LX7 pin and regulates the current by FB7 voltage. The LED current is defined by the FB7 voltage as well as the external resistor between FB7 and GND. The FB7 regulation voltage can be set in 31 steps from 8mV to 250mV, typically, via I^{2}C interface. If CH7 works in synchronous step-up mode, it integrates synchronous step-up mode with an internal MOSFET and internal compensation to output a voltage up to 15V. The LED current is also set via an external resistor and FB7 regulation voltage.

Address		b[7] (MSB)	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0] (LSB)
0x0	Meaning	MOD7	SEQ56	EN56	EN7_DIM7 [4:0]				
	Default	0	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

MOD7	1	CH7 in step-up mode
	0	CH7 in current source mode

SEQ56	1	CH5/6 power on sequence is CH5 → CH6, power off sequence is CH6 → CH5
	0	CH5/6 power on sequence is CH6 → CH5, power off sequence is CH5 → CH6

EN56	1	Enable (turn on) CH5 and CH6 by preset sequence
	0	Disable (turn off) CH5 and CH6 by preset

Enable CH7 and define FB7 regulation voltage

EN7_DIM7 [4:0]	00000	Ch7 turn off
	00001 to 11111	Ch7 turn on and dimming ratio : VFB7 = EN7_DIM7 [4:0] / 31 x 0.25V

CH7 WLED Current Dimming Control

If CH7 is in synchronous step-up mode or current source mode, the WLED current is set by an external resistor. Regardless of the mode, dimming is always controlled by the I^2C interface.

The WLED current can be set by the following equations :

ILED (mA) = [250mV / R (W)] x EN7_DIM7 [4:0] / 31

where R is the current sense resistor from FB7 to GND and EN7_DIM7 [4:0] / 31 ratio refers to the I^2C control register file. It is recommended that CH7 input power connects to the node SYS in order to prevent abnormal CH7 start-up.

VDDM Bootstrap

To support bootstrap function, the RT5002 includes a power selection circuit which selects between SYS and PVD1 to create the internal node voltage VDDI and VDDM.

VDDM is the power of the RT5002 PMU control circuits which must be connected to an external decoupling capacitor by way of the VDDM pin. VDDI is the power input of the RTC LDO. The output PVD1 of CH1 can bootstrap VDDM and VDDI. The RT5002 includes UVLO circuits to monitor VDDM and SYS voltage status.

RTC LDO

The RT5002 provides a 3.3V output LDO for real-time clock. The LDO features low quiescent current (3μA) and high output voltage accuracy. This LDO is always on, even when the system is shut down. For better stability, it is recommended to connect a 0.1μF capacitor to the RTCPWR pin. The RTC LDO includes pass transistor body diode control to avoid the RTCPWR node from back-charging into the input node VDDI.

Power On/Off Sequence for CH1 to CH4

EN1234 will turn on/off CH1 to CH4 in preset sequence.

CH1 to CH4 Power on Sequence is :

When EN1234 goes high, CH1 will turn on first. 3.5ms after CH1 is turned on, CH3 will turn on. 3.5ms after CH3 is turned on, CH4 will turn on. 3.5ms after CH4 is turned on, CH2 will turn on.

CH1 to CH4 Power off Sequence is :

When EN1234 goes low, CH2 will turn off first and internally discharge output. When FB2 < 0.1V, CH4 will turn off and also internally discharge output via the LX4 pin. When FB4 < 0.1V, CH3 will turn off and internally discharge output via the LX3 pin. Likewise, when FB3 < 0.1V, CH1 will turn off and discharge output. After FB1 < 0.1V, CH1 to 4 shutdown sequence will be completed.

Charger Unit

The RT5002 includes a Li-ion battery charger with Automatic Power Path Management. The charger is designed to operate in below modes :

Pre-Charge Mode

When the output voltage is lower than 2.8V, the charging current will be reduced to a fast-charge current ratio set by R_{ISETA} to protect the battery life-time.

Fast-charge Mode

When the output voltage is higher than 3V, the charging current will be equal to the fast-charge current set by R_{ISETA}.

Constant Voltage Mode

When the output voltage is near 4.2V and the charging current falls below the termination current, after a deglitch time check of 25ms, the charger will become disabled.

Re-charge Mode

When the chip is in charge termination mode, the charging current gradually goes down to zero. However, once the voltage of the battery drops to below 4.1V, there will be a deglitch time of 100ms and then the charging current will resume again.

I²C Register for Charging Status Setting

Address		b[7] (MSB)	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0] (LSB)
0x2	Meaning	ISETU	ISETL	USUS	NoBAT	EOC	PGOOD	TS_FAULT	$\overline{SAFE}$
	Default	1	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R	R	R	R	R

ISETU and ISETL : Set VIN Input Current Limit

ISETU	ISETL	VIN Input Current Limit
0	0	95mA
1	0	475mA
X	1	1.5A

USUS : VIN Suspend Control Input

USUS	1	Suspend
	0	No Suspend

Battery Installation Detection

NoBAT	1	No Battery Installed (TS > 90% of VP)
	0	BAT Installed (TS < 90% of VP)

End_Of_Charge Status

EOC	1	Charging Done or Recharging after Termination
	0	During Charging

VIN Power Good Status

PGOOD	0	$V_{IN} < V_{UVLO}$
	0	$V_{UVLO} < V_{IN} < V_{BAT} + V_{OS_H}$
	1	$V_{BAT} + V_{OS_H} < V_{IN} < V_{OVP}$
	0	$V_{IN} > V_{OVP}$

Temperature Sensing Status

TS_FAULT	1	TS is at fault (too cold, too hot) or VP triggers UVLO.
	0	TS and VP are normal.

Charger Safety Timer Status

$\overline{SAFE}$	1	Safety timer expired.
	0	Otherwise

Interrupt Indicator

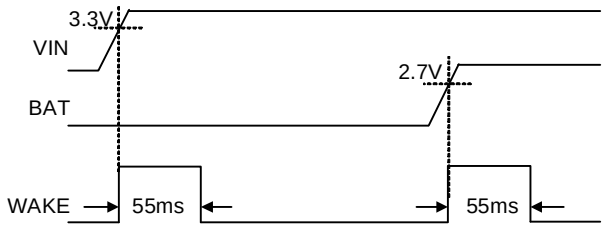
The RT5002 provides the interrupt indicator output pin ($\overline{INT}$). $\overline{INT}$ is an open drain pin.

When the status bits (PGOOD, TS_FAULT, EOC, $\overline{SAFE}$) of I^2C register address 0x2 toggle, the $\overline{INT}$ is set to be low. After Reg 0x2 is read or PMU turn off, $\overline{INT}$ goes high.

Wake-Up Detector

Wake-Up Detector detects VIN or BAT plug-in events. Once one of them plug-in, WAKE pin asserts one 55ms-width high pulse. The timing diagram is shown below.

WAKE Timing Diagram



Battery Installation Detection

RT5002 also detect TS voltage to judge the battery installation status. If PMU is enabled but TS voltage > 90% of VP node voltage, RT5002 would set the bit NoBAT = 1 in I^2C register bank 0x2.

End_Of_Charge (EOC) Status

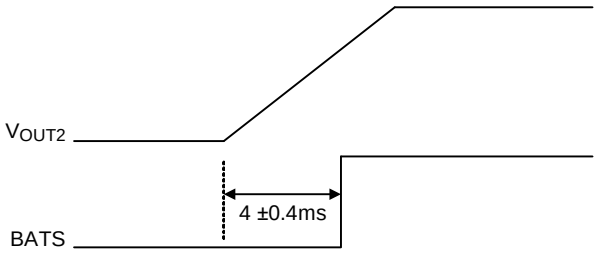
The bit EOC in I^2C register bank 0x2 can show the EOC status. If EOC = 1, the Charger is in EOC State.

Suspend Mode

Set USUS = 1, and the charge will enter Suspend Mode. In Suspend Mode, $I_{USUS\,(MAX)}$ < 300μA.

Battery Sense

When PMU is turned on, BATS = 59.8% x BAT, The RT5002 detects the battery level from BATS voltage level.



Charge State

Charger State	Bit EOC	Bit PGOOD	Bit $\overline{SAFE}$
Charging	0	1	0
Charging Suspended by Thermal Loop	0	1	0
Safety Timers Expired	0	1	1
Charging Done	1	1	0
Recharging after Termination	1	1	0
IC Disabled or no Valid Input Power	0	0	0

Address		b[7] (MSB)	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0] (LSB)
0x1	Meaning	TIMER [3:0]				$\overline{\text{ENCH}}$	$\overline{\text{JEITA}}$	ISET	VSET
	Default	0	1	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W

VIN Power Good Status

TIMER [3:0]	0000 to 1111	Fast Charge timeout period : t_{FCHG} = (TIMER [3:0] + 1) hours. (ISET = 1) Pre-Charge timeout period : $t_{PCHG} = t_{FCHG} / 8$

$\overline{\text{ENCH}}$	1	Disable charger
	0	Enable charger

$\overline{\text{JEITA}}$	1	Charger operation controlled by I^2C bits VSET and ISET
	0	Charger operation automatically in JEITA temperature standard

Half Charge Current Set Input

ISET	1	For I_{CHG1} : time = t_{FCHG}
	0	For I_{CHG2} : time = 2 x t_{FCHG}, $I_{CHG2} = I_{CHG1} / 2$

Battery Regulation Set Input

VSET	1	Battery regulation voltage is 4.2V
	0	Battery regulation voltage is 4.05V

Charging Current Decision

The charge current can be set according to the following equations :

If ISET = 1 (for I_{CHG1})

$$I_{CHG_FAST} = \frac{V_{ISETA}}{R_{ISETA}} \times 300$$

If ISET = 0 (for I_{CHG2})

$$I_{CHG_FAST} = \frac{V_{ISETA}}{R_{ISETA}} \times 150$$

$$I_{CHG_PRE} = 10\% \times I_{CHG_FAST}$$

Time Fault

During the fast charge phase, several events may increase the charging time.

For example, the system load current may have activated the APPM loop which reduces the available charging current or the device has entered thermal regulation because the IC junction temperature has exceeded T_{REG}.

However, once the duration exceeds the fault time, the register 0x2 bit [0] will be changed from 0 to 1, and the charge current will be reduced to about 1mA.

Time fault release methods :

(1) Re-plug power

(2) Toggle EN

(3) Enter/exit suspend mode

(4) Remove Battery

(5) OVP

If ISET = 1 (for I_{CHG1})

time = t_{FCHG}

If ISET = 0 (for I_{CHG2})

time = $2 \times t_{FCHG}$

JEITA Battery Temperature Standard

CV regulation voltage will change at the following battery temperature ranges : 0°C to 10°C and 45°C to 60°C.

CC regulation current will change at the following battery temperature ranges : 0°C to 10°C and 45°C to 60°C.

Battery Pack Temperature Monitoring

The battery pack temperature monitoring function can be realized by connecting the TS pin to an external Negative Temperature Coefficient (NTC) thermistor to prevent over temperature condition. Charging is suspended when the voltage at the TS pin is out of normal operating range. The internal timer is then paused, but the value is maintained.

When the TS pin voltage returns back to normal operating range, charging will resume and the safe charge timer will continue to count down from the point where it was suspended.

The 3.3V at VP pin is buffered by the RT5002 once it is in charging state or its PMU part is enabled.

For 100kΩ NTC thermistor, the input pin, TSSEL, should be connected to GND. For 10kΩ NTC thermistor, the input pin, TSSEL, should be connected to VIN. TSSEL determines the TS threshold levels for 0°C and 60°C. It also defines the TS threshold levels used in JEITA operation. The choosing method of R1 and R2 to meet battery temperature monitoring is shown below :

Case 1 : TSSEL = L (For 100kΩ NTC) :

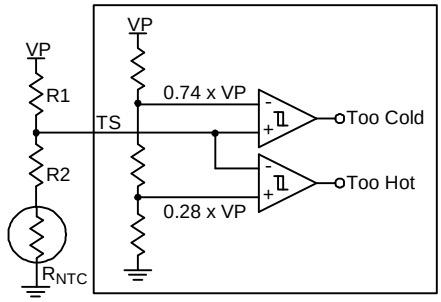


Figure 1

Too Cold Temperature

$R_{COLD} = R_{NTC}$

Too Hot Temperature

$R_{HOT} = R_{NTC}$

$$\frac{R2 + R_{COLD}}{R_{COLD} + R1 + R2} = 0.74 \quad (1)$$

$$\frac{R2 + R_{HOT}}{R_{HOT} + R1 + R2} = 0.28 \quad (2)$$

Form (1), (2)

$$R1 = \frac{R_{COLD} - R_{HOT}}{2.457}$$

$$R2 = 0.389 \times R1 - R_{HOT}$$

If R2 < 0

$$\frac{R_{COLD}}{R_{COLD} + R1} = 0.74 \quad (3)$$

Form (3)

$$R1 = \frac{R_{COLD}}{0.74} - R_{COLD}$$

Case 2 : TSSEL = H (For 10kΩ NTC) :

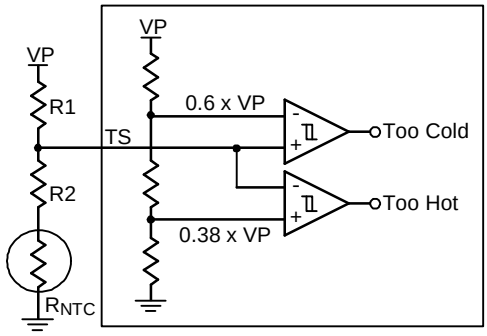


Figure 2

Too Cold Temperature

$R_{COLD} = R_{NTC}$

Too Hot Temperature

$R_{HOT} = R_{NTC}$

$$\frac{R2 + R_{COLD}}{R_{COLD} + R1 + R2} = 0.6 \quad (1)$$

$$\frac{R2 + R_{HOT}}{R_{HOT} + R1 + R2} = 0.38 \quad (2)$$

Form (1), (2)

$$R1 = \frac{R_{COLD} - R_{HOT}}{0.9}$$

$$R2 = 0.6 \times R1 - R_{HOT}$$

If R2 < 0

$$\frac{R_{COLD}}{R_{COLD} + R1} = 0.6 \quad (3)$$

Form (3)

$$R1 = \frac{R_{COLD}}{0.6} - R_{COLD}$$

The Control Temperature Used in JEITA Operation :

The above calculation gives R1 and R2. JEITA control thresholds for full charging current and 4.2V regulation voltage are at TS/VP ratio = 40% and 54% (for TSSEL = H), 35% and 64% (for TSSEL = L). With the ratio, the corresponding NTC thermistor resistances from the resistors in the voltage divider circuit can be obtained. According to the NTC resistances, the corresponding temperatures can be found. The two temperatures are the control temperatures used in JEITA operation.

Power Switch

For the charger, there are three power scenarios :

(1) When a battery and an external power supply (USB or adapter) are connected simultaneously :

If the system load requirements exceed that of the input current limit, the battery will be used to supplement the current to the load. However, if the system load requirements are less than that of the input current limit, the excess power from the external power supply will be used to charge the battery.

(2) When only the battery is connected to the system :

The battery provides the power to the system.

(3) When only an external power supply is connected to the system :

The external power supply provides the power to the system.

Input DPM Mode

For the charger, the input voltage is monitored when USB100 or USB500 is selected. If the input voltage is lower than VDPM, the input current limit will be reduced to stop the input voltage from dropping any further. This can prevent the IC from damaging improperly configured or inadequately designed USB sources.

APPM Mode

Once the sum of the charging and system load currents becomes higher than the maximum input current limit, the SYS pin voltage will be reduced. When the SYS pin voltage is reduced to VAPPM, the RT5002 will automatically operate in APPM mode. In this mode, the charging current is reduced while the SYS current is increased to maintain system output. In APPM mode, the battery termination function is disabled.

Battery Supplement Mode Short Circuit Protect

In APPM mode, the SYS voltage will continue to drop if the charge current is zero and the system load increases beyond the input current limit. When the SYS voltage decreases below the battery voltage, the battery will kick in to supplement the system load until the SYS voltage rises above the battery voltage.

While in supplement mode, there is no battery supplement current regulation. However, a built-in short circuit protection feature is available to prevent any abnormal current situations. While the battery is supplementing the load, if the difference between the battery and SYS voltage becomes more than the short circuit threshold voltage, SYS will be disabled. After a short circuit recovery time, t_{SHORT_R}, the counter will be restarted. In supplement mode, the battery termination function is disabled. Note that for the battery supply mode exit condition, VBAT-VSYS < 0V.

Thermal Regulation and Thermal Shutdown

The charger provides a thermal regulation loop function to monitor the device temperature. If the die temperature rises above the regulation temperature, TREG, the charge current will automatically be reduced to lower the die temperature. However, in certain circumstances (such as high VIN, heavy system load, etc.) even with the thermal loop in place, the die temperature may still continue to increase. In this case, if the temperature rises above the thermal shutdown threshold, TSD, the internal switch between VIN and SYS will be turned off. The switch between the battery and SYS will remain on, however, to allow continuous battery power to the load. Once the die temperature decreases by ΔTSD, the internal switch between VIN and SYS will be turned on again and the device returns to normal thermal regulation.

The internal thermal feedback circuitry regulates the die temperature to optimize the charge rate for all ambient temperatures.

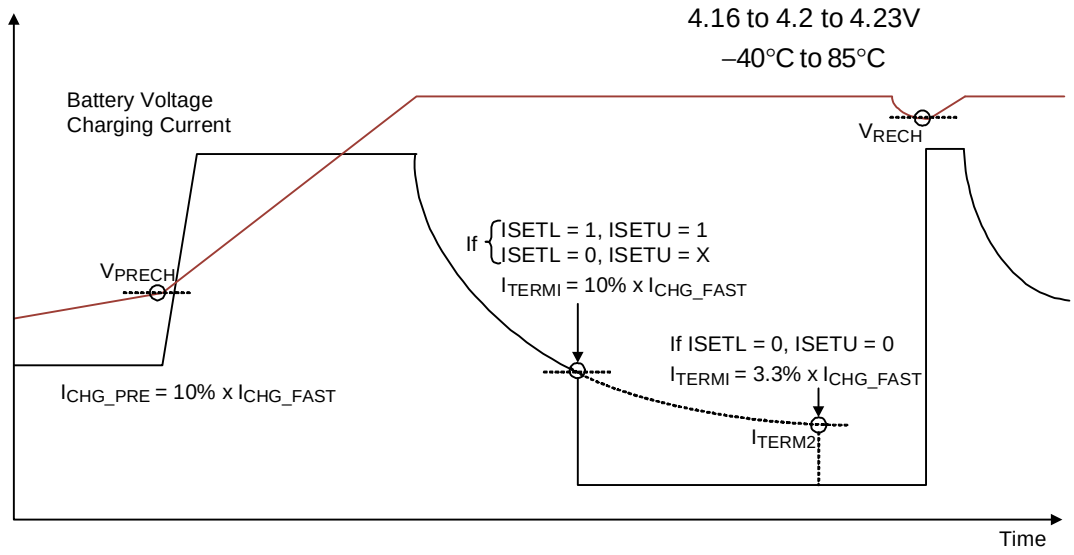
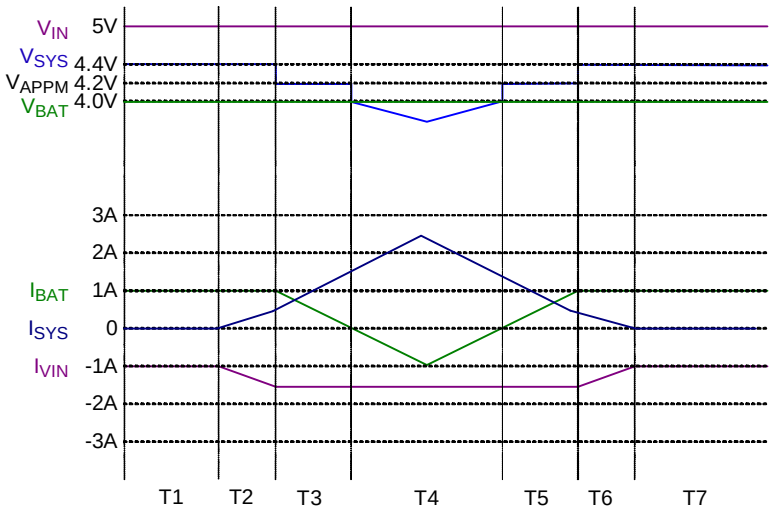


Figure 3

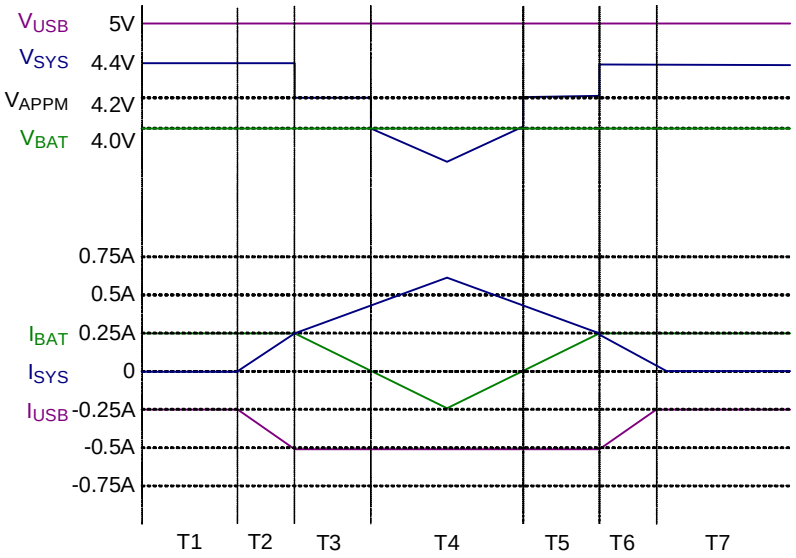
APPM Profile

1.5A Mode :



	I_{SYS}	V_{SYS}	I_{VIN}	I_{BAT}
T1, T7	0	SYS Regulation Voltage	CHG_MAX	CHG_MAX
T2, T6	< I_{VIN_OC} – CHG_MAX	SYS Regulation Voltage	I_{SYS} + CHG_MAX	CHG_MAX
T3, T5	> I_{VIN_OC} – CHG_MAX < I_{VIN_OC}	Auto Charge Voltage Threshold	V_{IN_OC}	V_{IN_OC} – I_{SYS}
T4	> I_{VIN_OC}	V_{BAT} – I_{BAT} x $R_{DS(ON)}$	V_{IN_OC}	I_{SYS} – I_{VIN_OC}

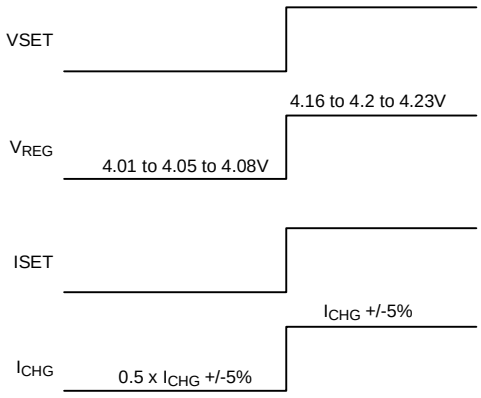
USB 500mA Mode :



	I_{SYS}	V_{SYS}	I_{USB}	I_{BAT}
T1, T7	0	SYS Regulation Voltage	CHG_MAX	CHG_MAX
T2, T6	< I_{VIN_OC} (USB) – CHG_MAX	SYS Regulation Voltage	I_{SYS} + CHG_MAX	CHG_MAX
T3, T5	> I_{VIN_OC} (USB) – CHG_MAX < I_{VIN_OC} (USB)	Auto Charge Voltage Threshold	I_{VIN_OC} (USB)	I_{VIN_OC} (USB) – I_{SYS}
T4	> I_{VIN_OC} (USB)	V_{BAT} – I_{BAT} x $R_{DS(ON)}$	I_{VIN_OC} (USB)	I_{SYS} – I_{VIN_OC} (USB)

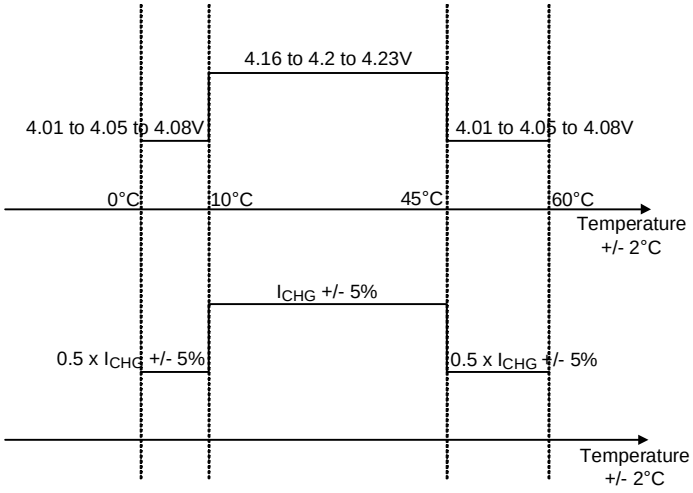
VSET vs. V_{REG}, ISET vs. I_{CHG}

When $\overline{JEITA}$ = 1, V_{REG} and I_{CHG} are set by the bits VSET and ISET, respectively.

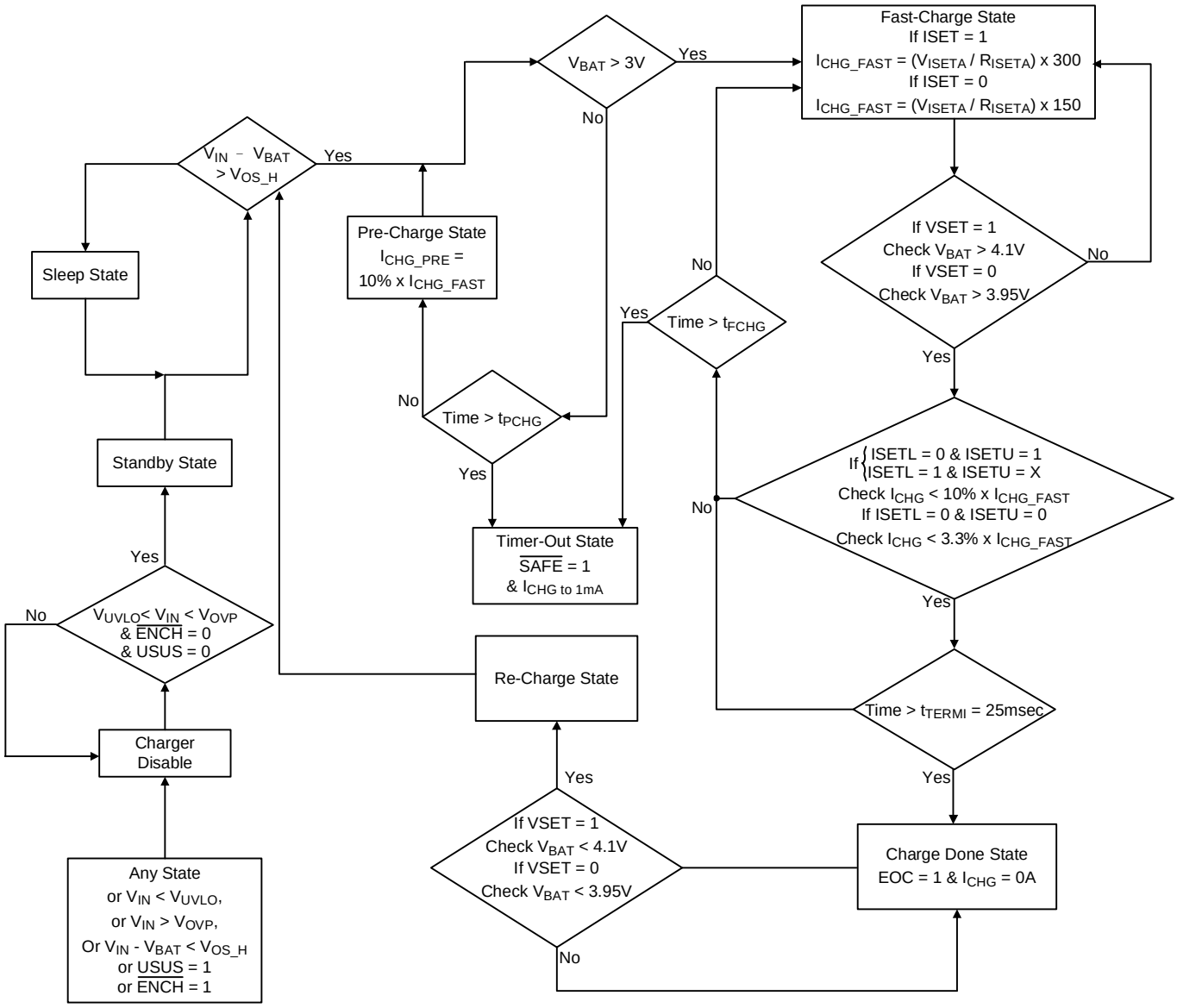


When $\overline{JEITA}$ = 0, V_{REG} and I_{CHG} follows JEITA temperature standard.

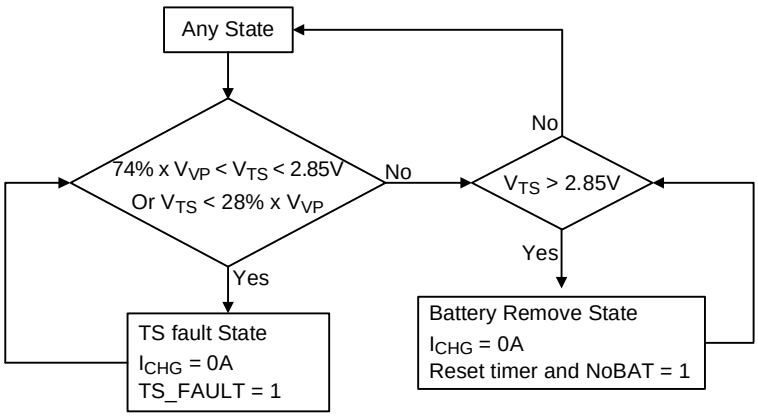
For JEITA Battery Temperature Standard :
CV regulation voltage will change at the following battery Temp ranges
0°C to 10°C and 45°C to 60°C
CC regulation current will change at the following battery Temp ranges
0°C to 10°C and 45°C to 60°C



RT5002 Operation State Diagram for Charging

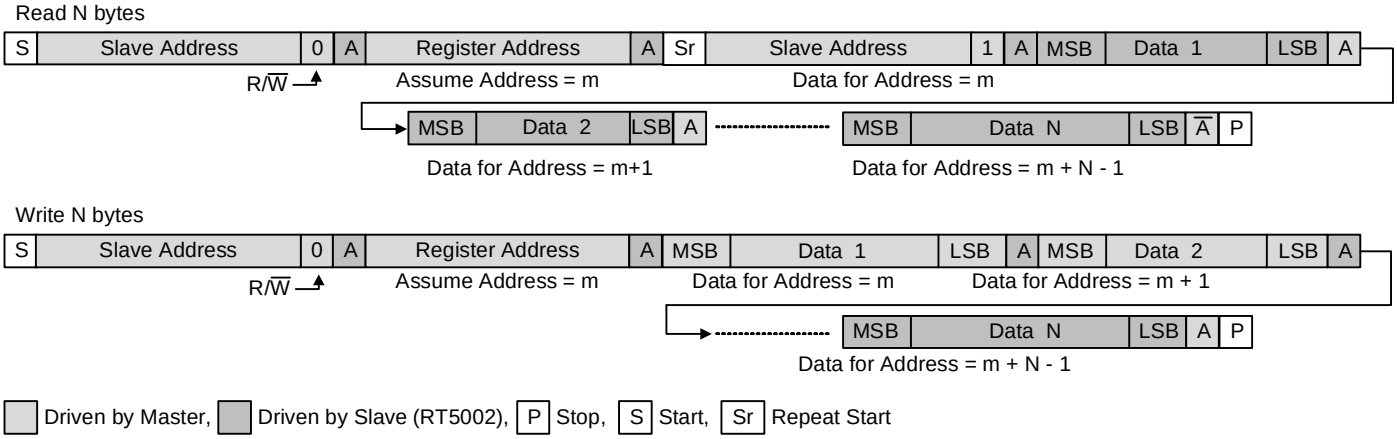


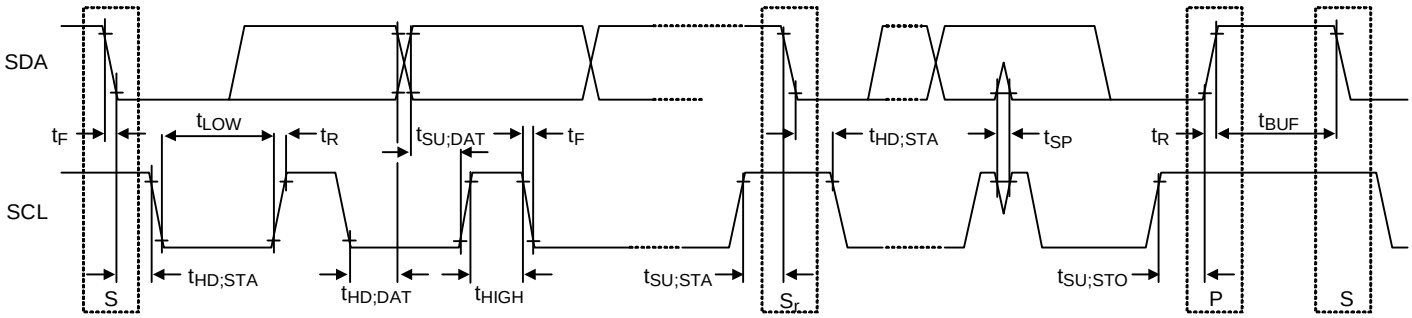
Operation State Diagram for TS Pin (TSSEL = L)



I²C Interface

The RT5002 I²C slave address is by default = 0011000 (7bits), but if customers request, the slave address can be changed to 0011010 (7bits). The I²C interface supports fast mode (bit rate up to 400kb/s). The write or read bit stream (N>=1) is shown below :





I²C Register File

Address		b[7] (MSB)	b[6]	b[5]	b[4]	b[3]	b[2]	b[1]	b[0] (LSB)
0x0	Meaning	MOD7	SEQ56	EN56	EN7_DIM7 [4:0]				
	Default	0	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
0x1	Meaning	TIMER [3:0]				$\overline{\text{ENCH}}$	$\overline{\text{JEITA}}$	ISET	VSET
	Default	0	1	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R/W	R/W	R/W	R/W	R/W
0x2	Meaning	ISETU	ISETL	USUS	NoBAT	EOC	PGOOD	TS_FAULT	$\overline{\text{SAFE}}$
	Default	1	0	0	0	0	0	0	0
	Read/Write	R/W	R/W	R/W	R	R	R	R	R

Reset after EN1234 = L and PMU shutdown completely.

Thermal Considerations

For continuous operation, do not exceed absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated by the following formula :

$P_{D(MAX)} = (T_{J(MAX)} - T_A) / \theta_{JA}$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction to ambient thermal resistance.

For recommended operating condition specifications of the RT5002, the maximum junction temperature is 125°C and T_A is the ambient temperature. The junction to ambient thermal resistance, θ_{JA}, is layout dependent. For WQFN-40L 5x5 packages, the thermal resistance, θ_{JA}, is 36°C/W on a standard JEDEC 51-7 four-layer thermal test board. The maximum power dissipation at T_A = 25°C can be calculated by the following formula :

$P_{D(MAX)} = (125°C - 25°C) / (36°C/W) = 2.778W$ for

WQFN-40L 5x5 package

The maximum power dissipation depends on the operating ambient temperature for fixed $T_{J(MAX)}$ and thermal resistance, θ_{JA}. For the RT5002 package, the derating curve in Figure 4 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.

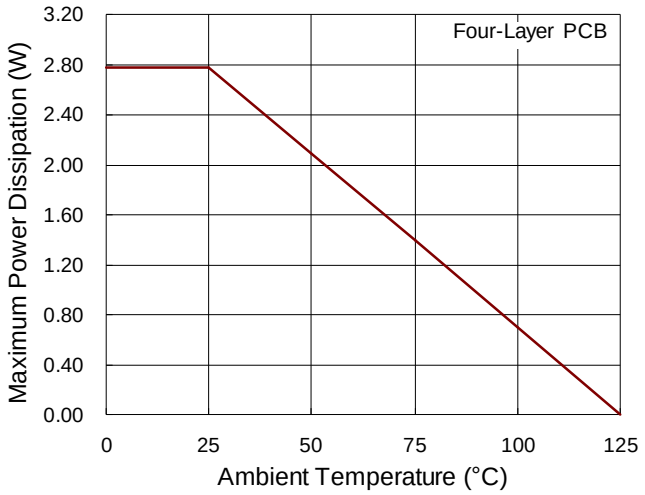


Figure 4. Derating Curves for RT5002 Package

Layout Considerations

For the best performance of the RT5002, the following PCB layout guidelines must be strictly followed.

- Place the input and output capacitors as close as possible to the input and output pins respectively for good filtering.
- Keep the main power traces as wide and short as possible.
- The switching node area connected to LX and inductor should be minimized for lower EMI.
- Place the feedback components as close as possible to the FB pin and keep these components away from the noisy devices.
- Connect the GND and Exposed Pad to a strong ground plane for maximum thermal dissipation and noise protection.
- The connection of RISETA should be isolated from other noisy traces. A short wire is recommended to prevent EMI and noise coupling.

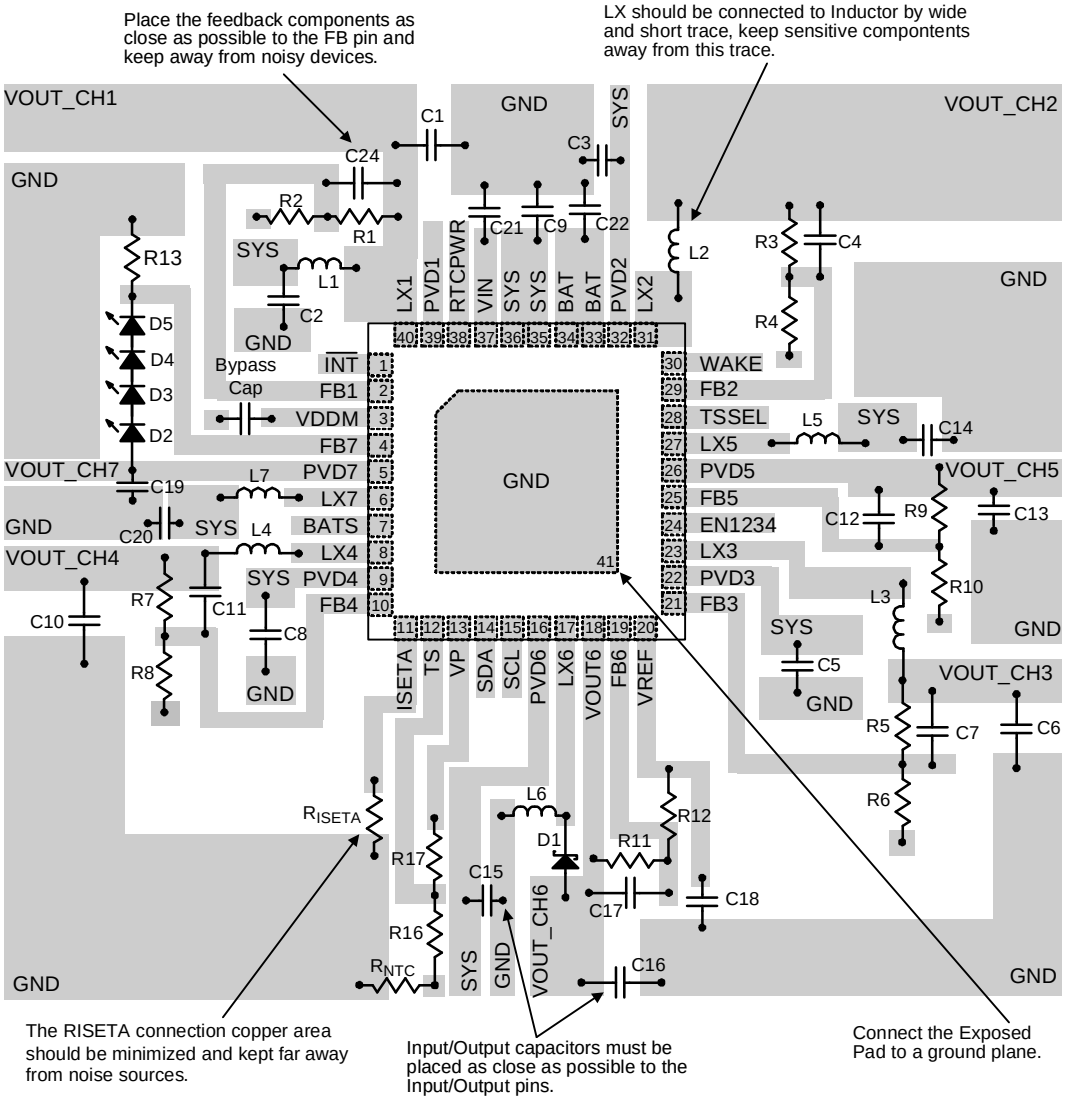


Figure 5. PCB Layout Guide

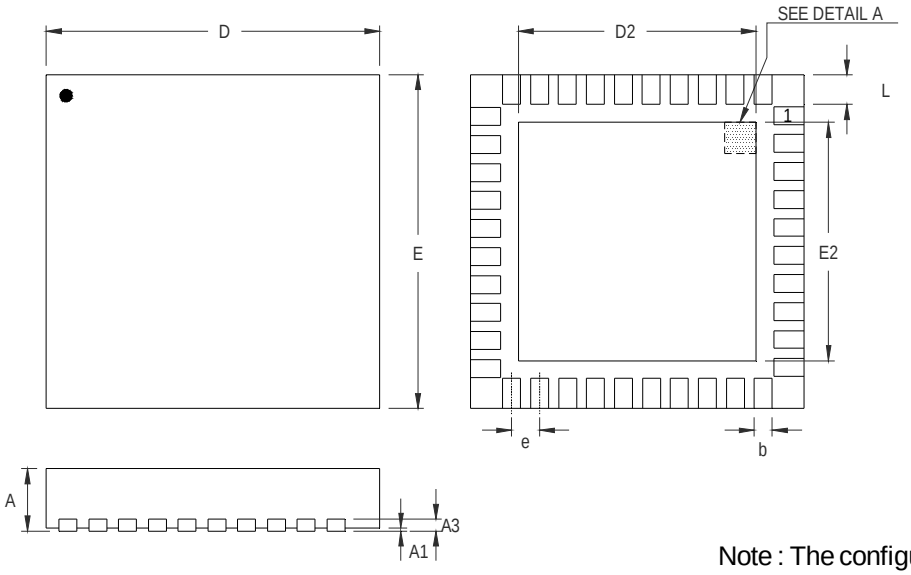
	Protection Type	Threshold (Typical) Refer to Electrical spec.	Protection Methods	IC Shutdown Delay Time	Reset Method
SYS	UVLO	SYS < 1.3V	PMU Shutdown.	No-delay	VDDM power reset or EN1234 pin set to low
VDDM	OVP	VDDM > 6V	Automatic reset at VDDM < 5.75V	100ms	VDDM power reset or EN1234 pin set to low
	UVLO	VDDM < 2.4V	PMU Shutdown.	No-delay	VDDM power reset or EN1234 pin set to low
CH1 Step-Up	Current limit	N-MOSFET current > 3A	N-MOSFET off, P-MOSFET off. Automatic reset at next clock cycle.	100ms	VDDM power reset or EN1234 pin set to low
	PVD1 OVP	PVD1 > 6V	N-MOSFET off, P-MOSFET off.	No-delay	VDDM power reset or EN1234 pin set to low
	PVD1 UVP	PVD1 < (VSYS – 0.8V) or PVD1 < 1.28V after soft-start end.	N-MOSFET off, P-MOSFET off.	100ms	VDDM power reset or EN1234 pin set to low
	FB1 UVP	FB1 < 0.4V after pre-charge	N-MOSFET off, P-MOSFET off	No-delay	VDDM power reset or EN1234 pin set to low
	FB1 Over Load (OL)	FB1 < 0.7V	PMU Shutdown when OL occur each cycle until 100ms.	100ms	VDDM power reset or EN1234 pin set to low
CH2 Step-Down	Current limit	P-MOSFET current > 1.8A	N-MOSFET off, P-MOSFET off. Automatic reset at next clock cycle.	100ms	VDDM power reset or EN1234 pin set to low
	FB2 UVP	FB2 < 0.4V after soft-start end.	N-MOSFET off, P-MOSFET off.	100ms	VDDM power reset or EN1234 pin set to low
	FB2 Over Load	FB2 < 0.7V	PMU Shutdown when OL occur each cycle until 100ms.	100ms	VDDM power reset or EN1234 pin set to low
CH3 Step-Down	Current limit	P-MOSFET current > 1.6A	N-MOSFET off, P-MOSFET off. Automatic reset at next clock cycle.	100ms	VDDM power reset or EN1234 pin set to low
	FB3 UVP	FB3 < 0.4V after soft-start end.	N-MOSFET off, P-MOSFET off.	100ms	VDDM power reset or EN1234 pin set to low
	FB3 Over Load	FB3 < 0.7V	PMU Shutdown when OL occur each cycle until 100ms.	100ms	VDDM power reset or EN1234 pin set to low
CH4 Step-Down	Current limit	P-MOSFET current > 1.6A	N-MOSFET off, P-MOSFET off. Automatic reset at next clock cycle.	100ms	VDDM power reset or EN1234 pin set to low
	FB4 UVP	FB4 < 0.4V after soft-start end.	N-MOSFET off, P-MOSFET off.	100ms	VDDM power reset or EN1234 pin set to low
	FB4 Over Load	FB4 < 0.7V	PMU Shutdown when OL occur each cycle until 100ms.	100ms	VDDM power reset or EN1234 pin set to low

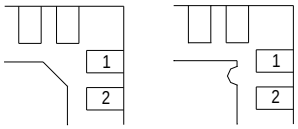
To be continued

	Protection Type	Threshold (Typical) Refer to Electrical spec.	Protection Methods	IC Shutdown Delay Time	Reset Method
CH5 Step-Up	Current limit	N-MOSFET current > 1.2A	N-MOSFET off, P-MOSFET off. Automatic reset at next clock cycle.	100ms	VDDM power reset or EN1234 pin set to low
	PVD5 OVP	PVD5 > 22V	N-MOSFET off, P-MOSFET off.	No-delay	VDDM power reset or EN1234 pin set to low
	FB5 UVP	FB5 < 0.6V after soft-start end.	N-MOSFET off, P-MOSFET off.	100ms	VDDM power reset or EN1234 pin set to low
	FB5 Over Load	FB5 < 1.1V	PMU Shutdown when OL occur each cycle until 100ms.	100ms	VDDM power reset or EN1234 pin set to low
	PVD5 UVP	PVD5 < (VSYS –0.2V)	N-MOSFET off, P-MOSFET off.	100ms	VDDM power reset or EN1234 pin set to low
CH6 Async Inverting	Current limit	P-MOSFET current > 1.5A	P-MOSFET off. Automatic reset at next clock cycle.	100ms	VDDM power reset or EN1234 pin set to low
	PVD6 OVP	PVD6 < -13V	P-MOSFET off.	No-delay	VDDM power reset or EN1234 pin set to low
	FB6 UVP	FB6 > 1.2V	P-MOSFET off.	100ms	VDDM power reset or EN1234 pin set to low
	FB6 Over Load	FB6 > 0.74V	PMU Shutdown when OL occur each cycle until 100ms.	100ms	VDDM power reset or EN1234 pin set to low
CH7 WLED	Current limit	N-MOSFET current > 0.8A	N-MOSFET off, P-MOSFET off. Automatic reset at next clock cycle.	100ms	VDDM power reset or EN1234 pin set to low
	PVD7 OVP	PVD7 > 15V	N-MOSFET off, P-MOSFET off. Shutdown CH7 by self	No-delay	VDDM power reset and Reg0x00[4 to 0] = 00000 reset or EN1234 pin set to low
Thermal	Thermal shutdown	Temperature > 155°C	All channels stop switching	No-delay	VDDM power reset or EN1234 pin set to low

	Protection Type	Threshold (Typical) Refer to Electrical Spec.	Protection Methods	Charger Shutdown Delay Time	Reset Method
VIN	VIN UVLO	VIN < 3.3V	No-charge	No-delay	No latch
	VIN OVP	VIN > 6.5V	No-charge	No-delay	No latch

Outline Dimension





DETAIL A

Pin #1 ID and Tie Bar Mark Options

Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.175	0.250	0.007	0.010
b	0.150	0.250	0.006	0.010
D	4.950	5.050	0.195	0.199
D2	3.250	3.500	0.128	0.138
E	4.950	5.050	0.195	0.199
E2	3.250	3.500	0.128	0.138
e	0.400		0.016	
L	0.350	0.450	0.014	0.018

W-Type 40L QFN 5x5 Package

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